

# **Renesas Power Management Solution (Portable Application, Server Application, AC/DC Application)**

# **1. Portable Application (Multi-channel DC/DC converters, Charger ICs)**

# Multi-channel DC/DC

# Renesas DC-DC Converter Proposal

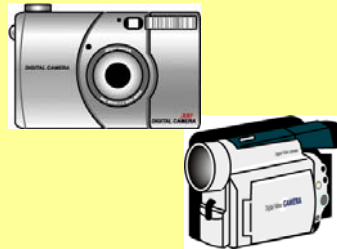
*Renesas application-specific DC-DC converter provide high performance and compact power designs for DSC*

## Multi DC-DC

**Provide higher performance**

- Built-in external components
- High speed switching
- High efficiency
- Fast response and High stability
- Large current driving
- Abundant protect function

**Smaller and thinner body!  
Higher performance!**



## Power Management (Custom)

**Integrate power management function**

- RTC
- Input/Output voltage surveillance
- Output sequence control
- Back-up battery Switching control
- Strobe charge, etc.

## SiP Solution

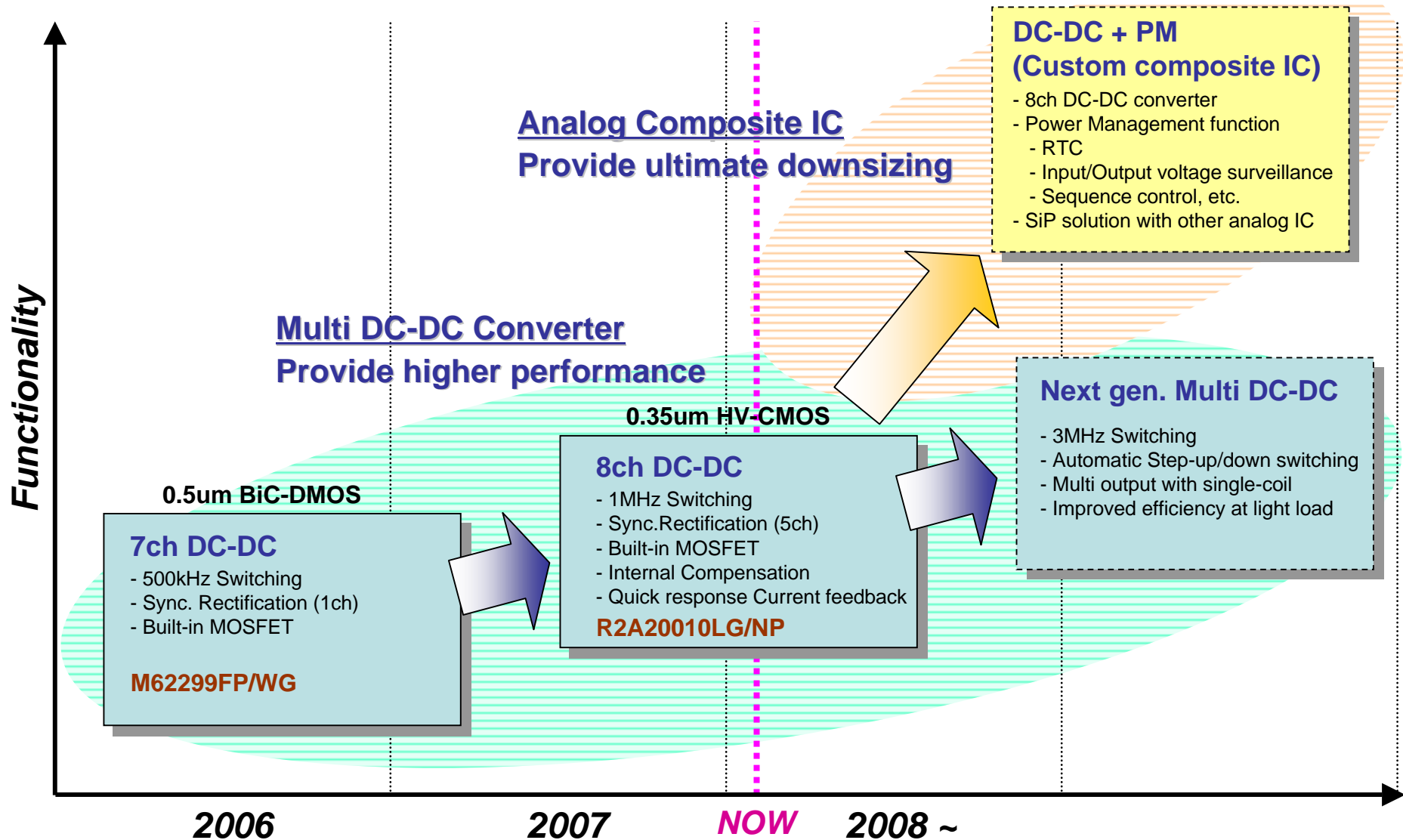
**Provide ultimate downsizing**

- SiP with Motor Driver IC, etc.

*Under planning*

*Under planning*

# Roadmap of Multi channel DC-DC converter



# Features of 8ch DC-DC R2A20010NP/LG

- Flexible 8ch architecture including the power supply for DDR-SDRAM(2.5V typ.)
- Minimal-class external components
- Higher efficiency and quick response

## 8-channel architecture

- 3 step-up
- 2 selectable step-up/Step-down
- 2 Step-down
- 1 Inverter

## Built-in external components

- Output MOSFET (5ch)
- Load switch (2ch)
- Phase compensate parts (All ch.)

## High efficiency synchronous rectification (5ch)

## Fast response current feedback mode (4ch)

## High speed switching

- 1MHz for Sync. rectifying ch
- 500kHz for Diode rectifying ch

## Bootstrap circuit (CH-5)

## Low voltage operation : 1.4V to 4.5V

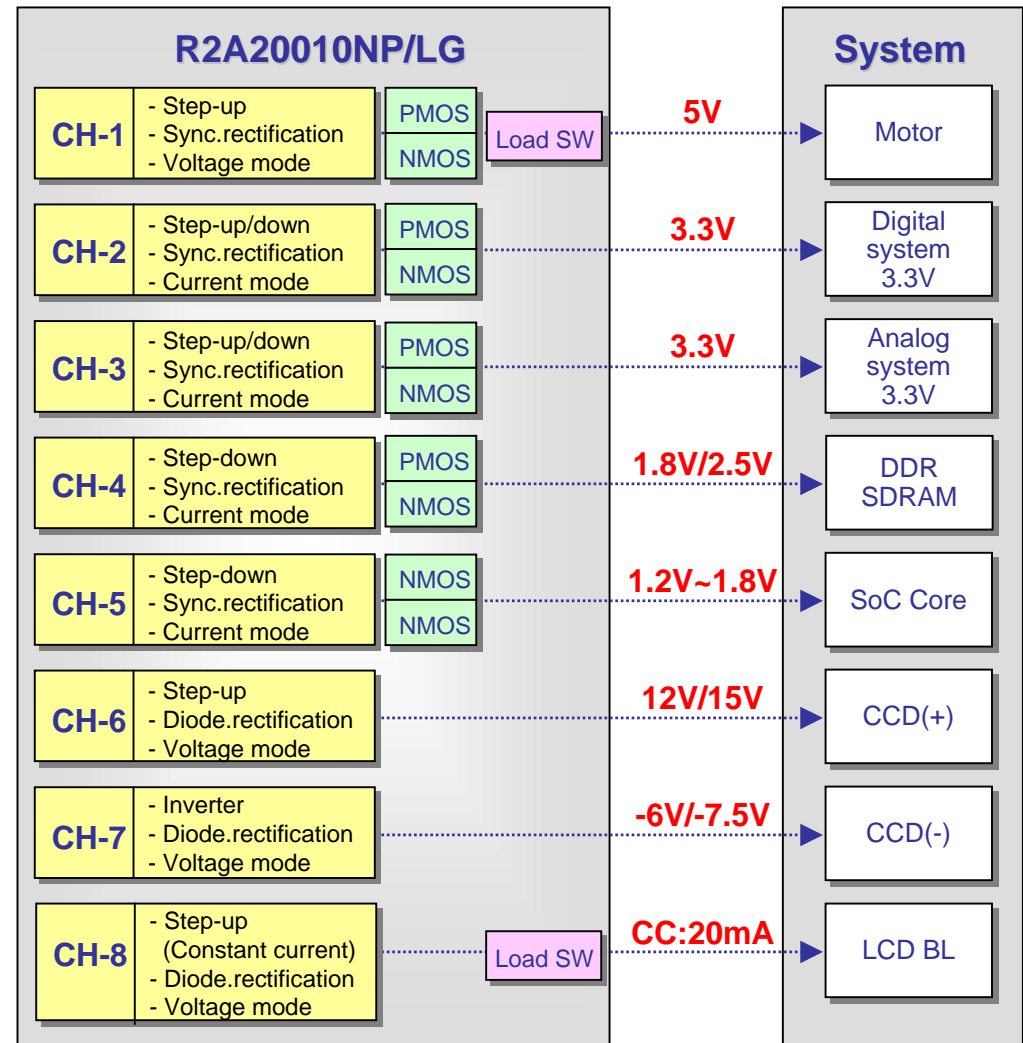
Corresponds to 1-cell Li-ion and 2-cell AA battery

## Dimmer control function for LCD BL (CH-8)

## Small Package

R2A20010NP : 48pin QFN (6 x 6mm)

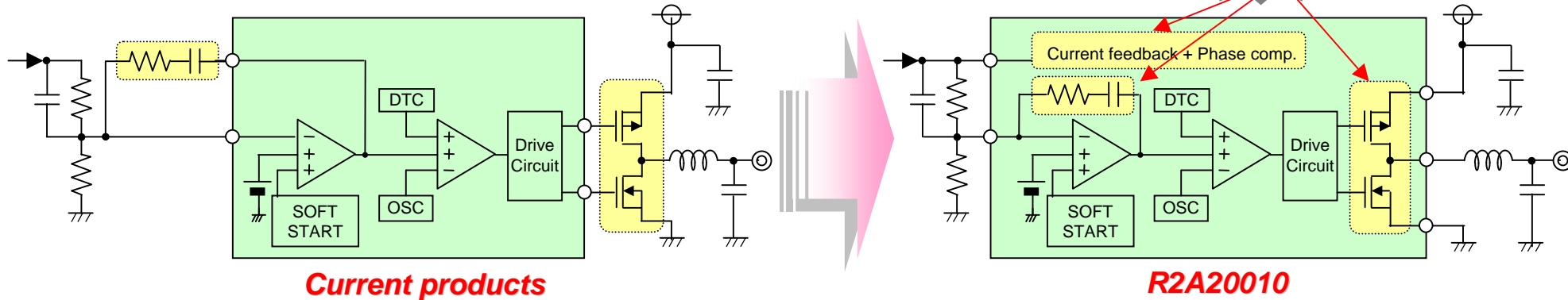
R2A20010LG : 49pin LGA (5 x 5mm)



# Key technologies for compact designs

*Realized fewer external parts(-31.5%) and smaller mounting area(-20.6%) compared with current products*

- Built-in Output MOSFET (for 5 sync. Rectification channels)
- Built-in phase compensation parts (for all channel)
- Built-in Load SW MOSFET (For 2 step-up channels)



## The number of external parts and the mounting area (Estimation)

[Conditions]

- Battery : Li-ion 1cell (3.0V to 4.2V)
- Output channel configuration

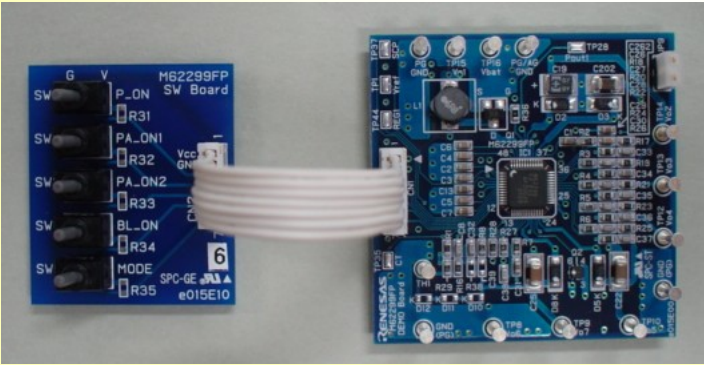
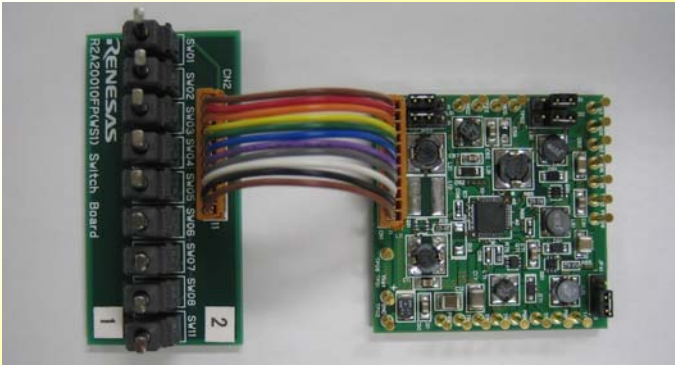
[Estimation result]

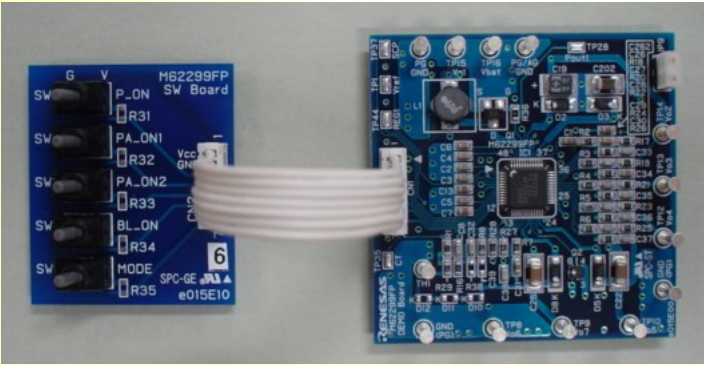
Output Voltage	Application	Conversion Type	Rectification
5.0V	Motor	Step-up from Battery	Sync.
3.3V	Digital 3.3V	Step-down from 5.0V	Sync.
3.3V	Analog 3.3V	Step-down from 5.0V	Sync.
2.5V	SDRAM	Step-down from Battery	Sync.
1.8V	SOC core	Step-down from Battery	Sync.
+15V	CCD(+)	Step-up from Battery	Diode
-7.5V	CCD(-)	Inverting from Battery	Diode
C.C.20mA	LCD BL	Step-up from Battery	Diode

	Area(mm <sup>2</sup> )	Current product		R2A20010	
		Quantity	Area(mm <sup>2</sup> )	Quantity	Area(mm <sup>2</sup> )
DC-DC Converter IC (QFN-48)	36.0	1	36.0	1	36.0
MOSFET	4.0	16	64.0	4	16.0
Inductor	16.0	8	128.0	8	128.0
Diode	4.2	4	16.6	4	16.6
Capacitor	1.3	39	45.5	30	35.1
Resistor	0.5	27	12.5	18	8.5
<b>Total</b>		<b>95</b>	<b>302.6</b>	<b>65</b>	<b>240.2</b>

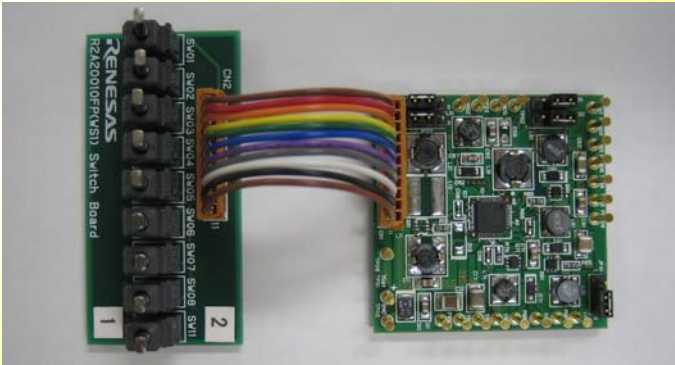
**The number of external parts : 31.6% reduced**  
**The mounting area : 20.6% reduced**

# Development support tools

	M62299		R2A20010	
Parts No.	M62299FP	M62299WG	R2A20010NP	R2A20010LG
Package	48pin QFN	49pin LGA	48pin QFN	49pin LGA
Application note	<i>available</i>		<i>available</i>	
Evaluation board	<i>available</i>	<i>available</i>	<i>available</i>	<i>available</i>
	 <p>&lt;M62299FP Evaluation board&gt;</p>		 <p>&lt;R2A20010NP Evaluation board&gt;</p>	



<M62299FP Evaluation board>



<R2A20010NP Evaluation board>



# Charger IC

# Renesas Charger ICs - Development Concept

## 1. Reduce mounting space by smaller PKG.

- Built-in MOSFET, current sense resistor
- Small packages

## 2. Easy set design

- Constant current, constant voltage charge control for Lithium-ion battery

## 3. Higher performance

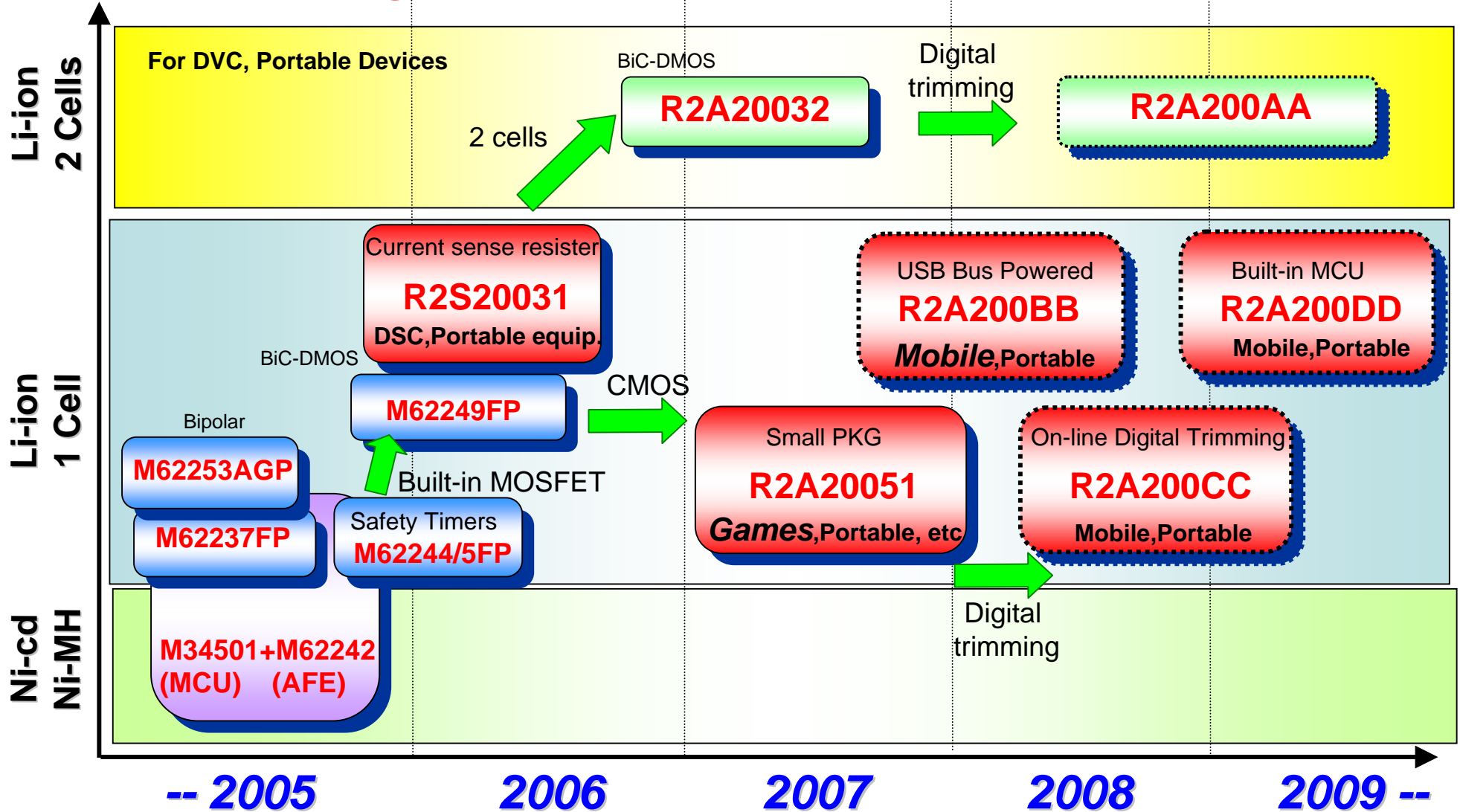
- Highly accurate charge control with internal high precision voltage reference
- Various protection functions

## 4. Low cost

- Optimized CMOS process technology

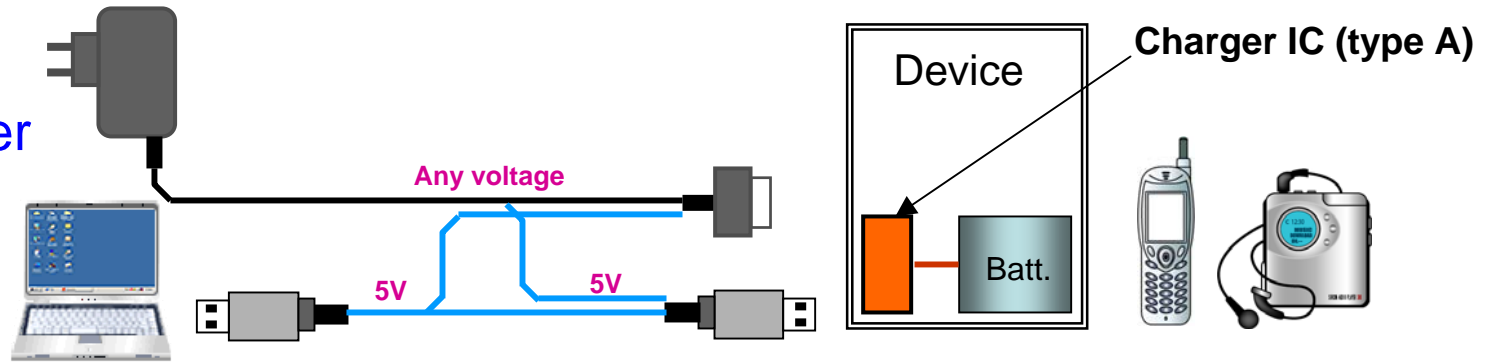
# Roadmap for Battery Charger ICs

Built-in Digital Trimmer, OTP, MCU, MOS FET, Timer, USB, I2C, etc.

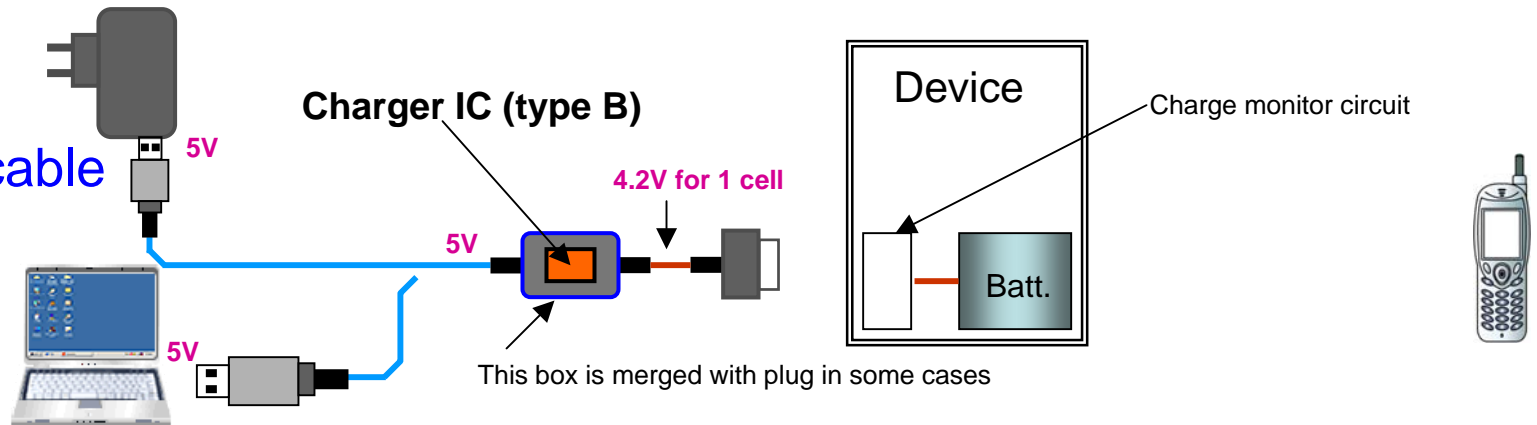


# Battery Charger Configuration (1)

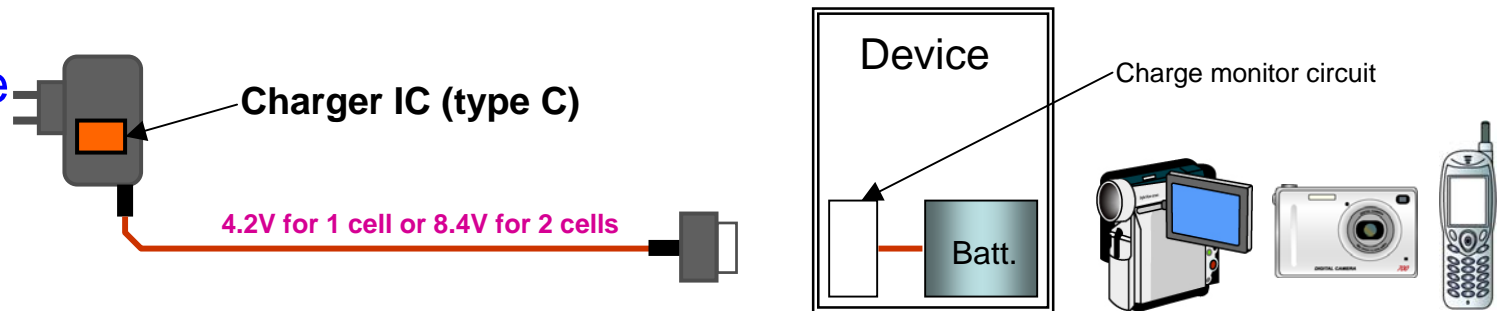
## 1. Internal charger



## 2. USB adaptor cable charger

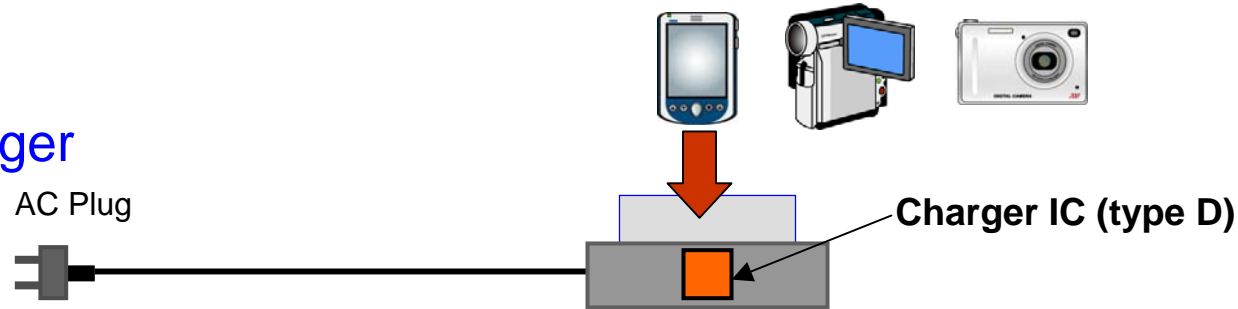


## 3. AC adaptor type charger

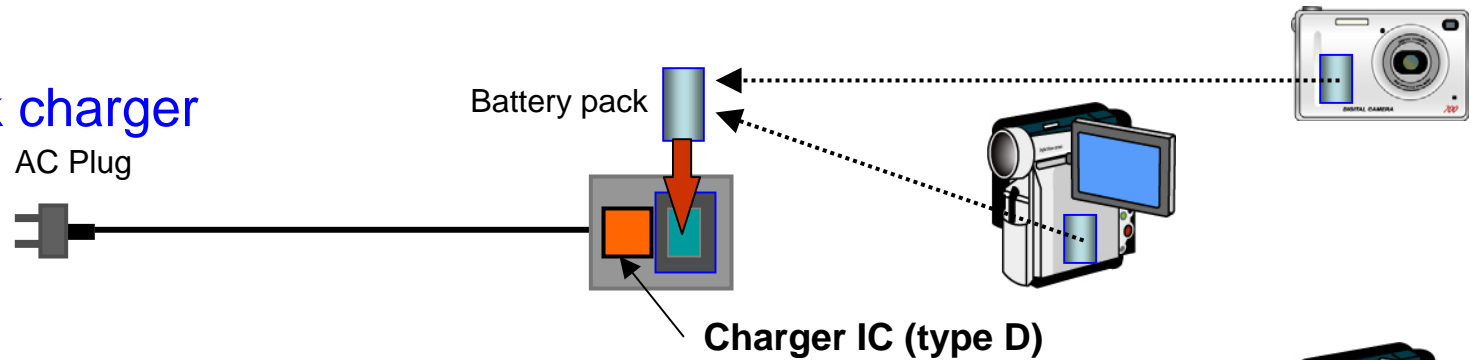


# Battery Charger Configuration (2)

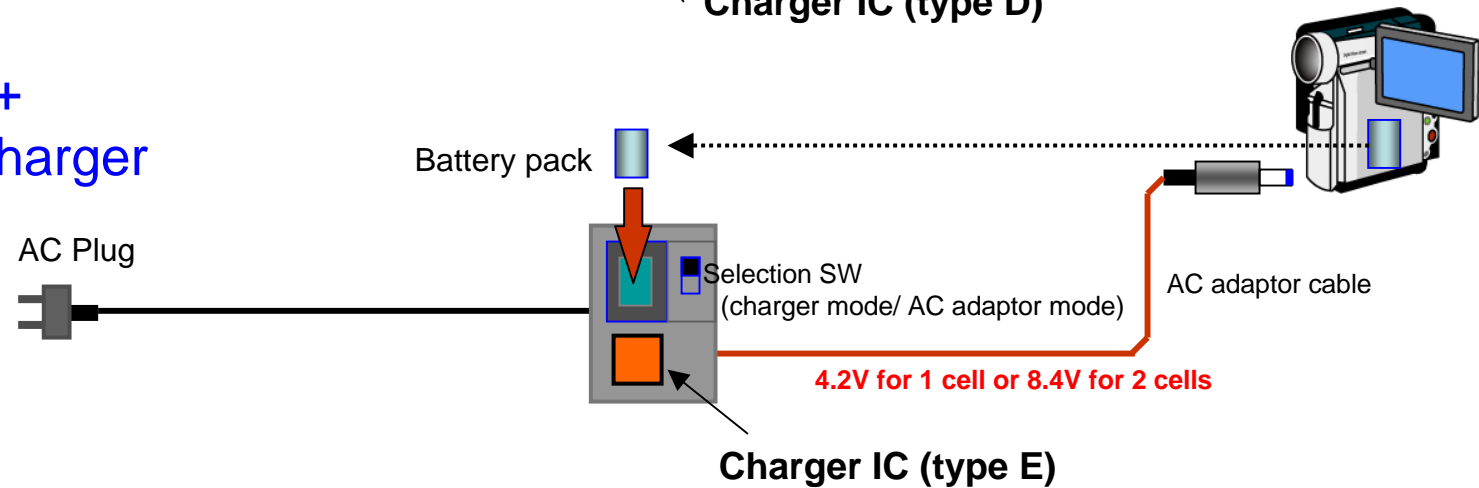
## 4. Cradle/ charger



## 5. Battery pack charger



## 6. AC adaptor + battery pack charger



# Type of Battery Charger IC & Renesas ICs

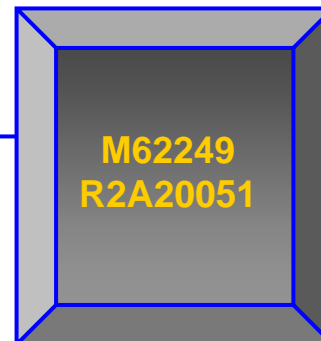
**Type A:** (No.1) • Supports a few type of battery (only attachable batteries)  
• Regulated DC input  
• Small package

• Mobile phones  
• MP3 players/ PMPs

**Type B:** (No.2) • Regulated 5V DC input  
• Small package

-> **Charger IC is better if it needs small size and small current dissipation**

• Some of mobile phones

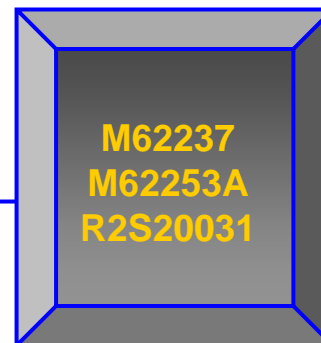


**Type C:** (No.3) • Feedback to primary (PWM) side with photo-coupler  
-> **Charger IC is better for higher reliable system and easy design**

• DVC  
• Some of mobile phones  
• Some of DSC

**Type D:** (No.4&5) • Supports a few type of battery (only attachable batteries)  
• Feedback to primary (PWM) side with photo-coupler

• PDA  
• DSC  
• Some of DVC



**Type E:** (No.6) • Supports a few type of battery (only attachable batteries)  
• AC-DC converter function, as well as battery charger

• DVC accessories



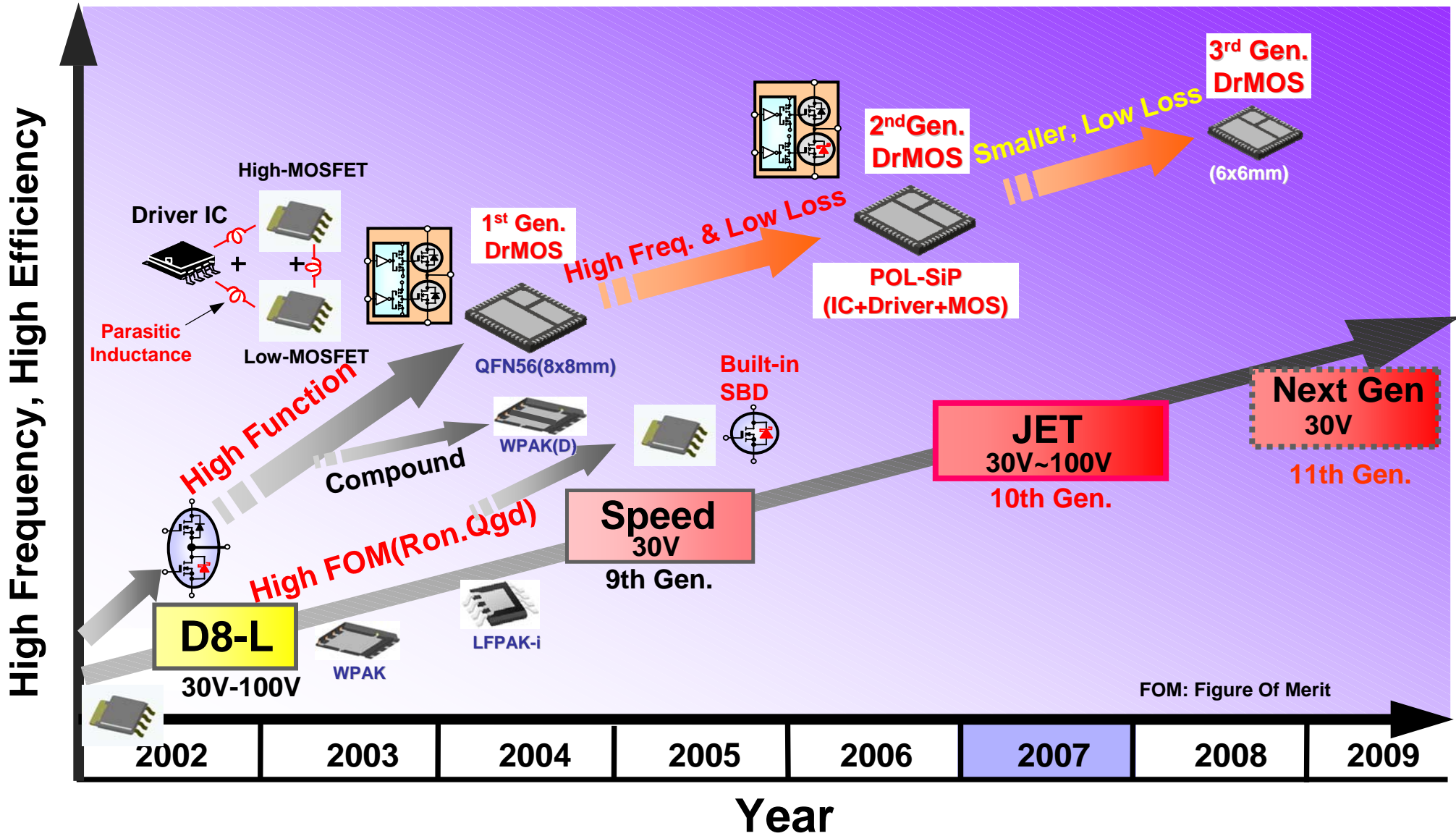
# Battery Charger IC Line-up

	Bat. Type			V <sub>CC</sub> (V)	Function									Package	Protection						Supplements		
	Li-ion	NiCd/NiMH	Cell count		Built-in MOS FET	Built-in current sense resistor	Primary control	MCU I/F	LED drive	Battery identification	AC adaptor detection	Setable charge termination	Pre-charge/Trickle charge		Re-charge	Over-discharge detection	Over-voltage detection	Over current detection	Temperature detection	Safety timer		Thermal protection	Compulsory charge stop
M62240		○	1	3-15			○		1		○			○	SOP20		○	○	○	○			
M62237	○		1	2.5-15			○								SOP8								Const. current/voltage
M62244	○		1	3-6.5					2		○	○	○	SSOP20	○	○	○	○	○			○	
M62245	○		1	3-6.5					2		○	○		SSOP16	○	○	○	○	○				
M62249	○		1	4.75-6.1	○				1		○	○	○	QFN28	○	○		○	○			○	
M62253A	○		1	5-15					2		○	○	○	SSOP16	○			○					Chattering free
R2S20030	○		1	4.75-6	○	○			1		○	○	○	QFN28		○		○	○	○			
R2S20031	○		1	3-6.5	○	○	○		2		○	○	○	SSOP20	○	○	○	○	○	○			
R2A20051	○		1	4-6	○	○			1		○	○	○	SON10	○	○			○	○	○		Die temp. monitor
M62242	○	○	1,2	5.3-15				○		○		○	○	SSOP16	Realized with MCU								
M62255	○	○	3,4	7.5-22				○			○			SSOP24	Realized with MCU						DC-DC type regulator		

## **2. Server Application (Jet Series MOSFET, DrMOS, SiP-POL)**

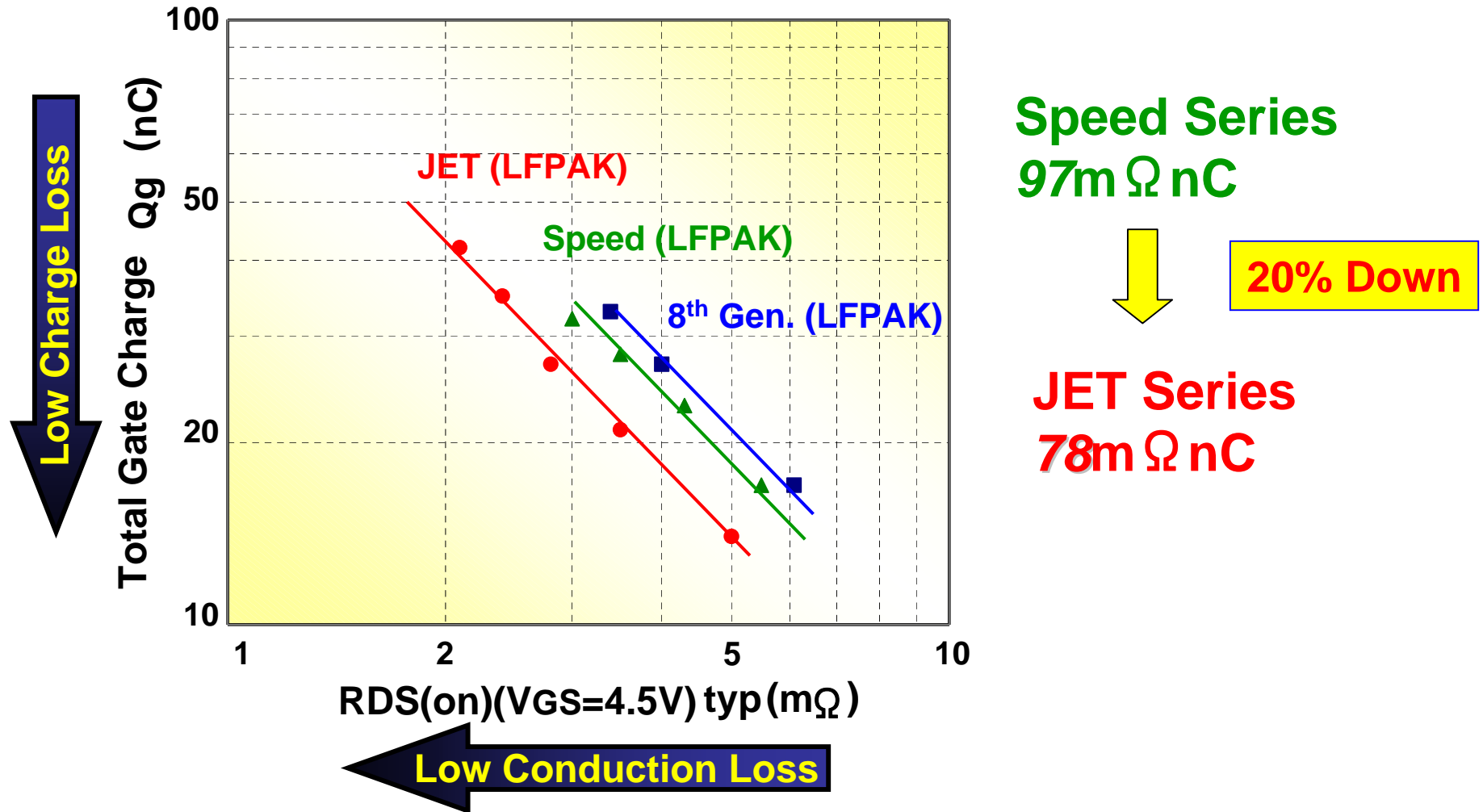


# Renesas Low Voltage MOSFET Road Map

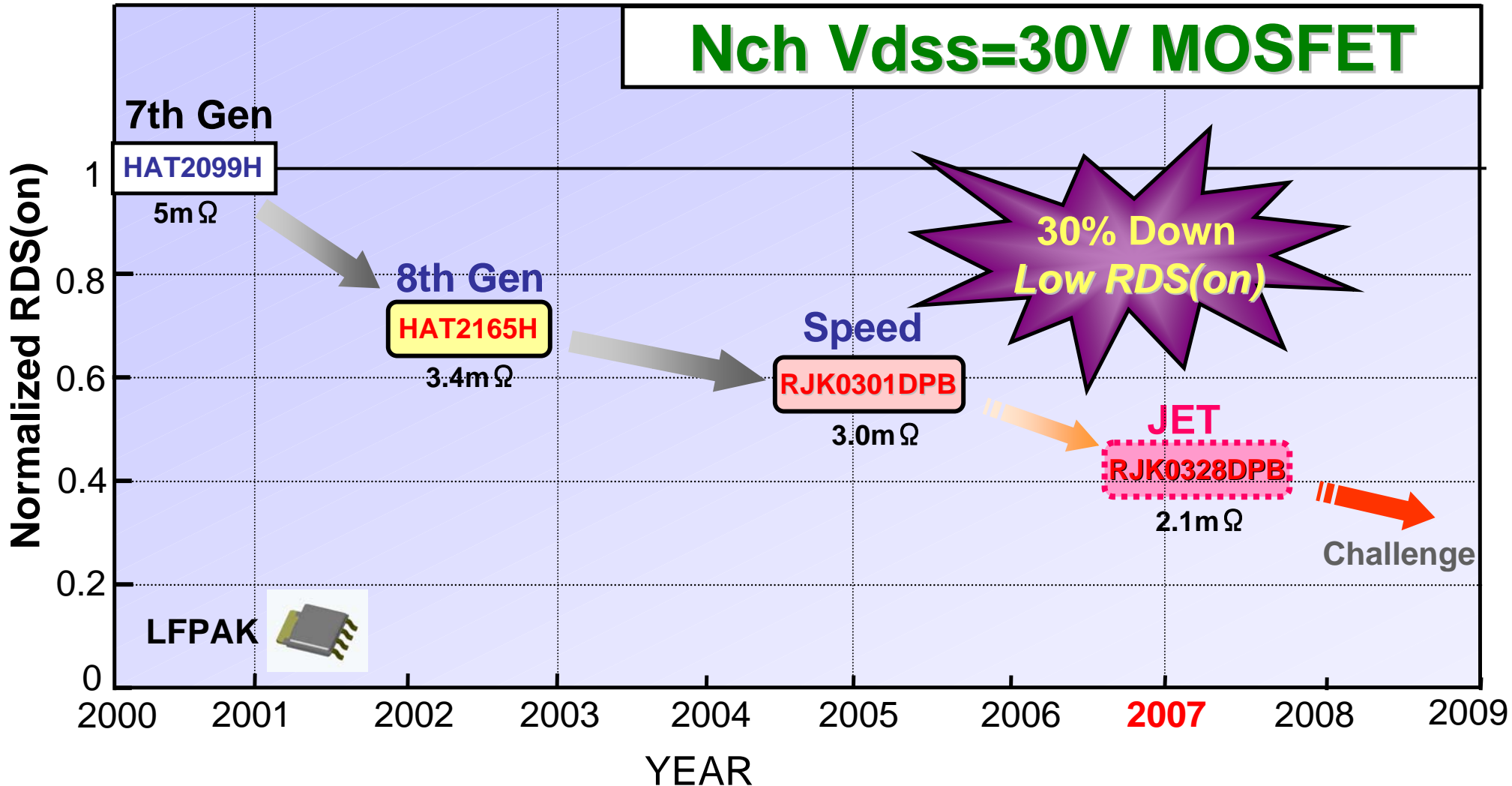


# Feature of JET series in Low-side ( $V_{DSS}=30V$ )

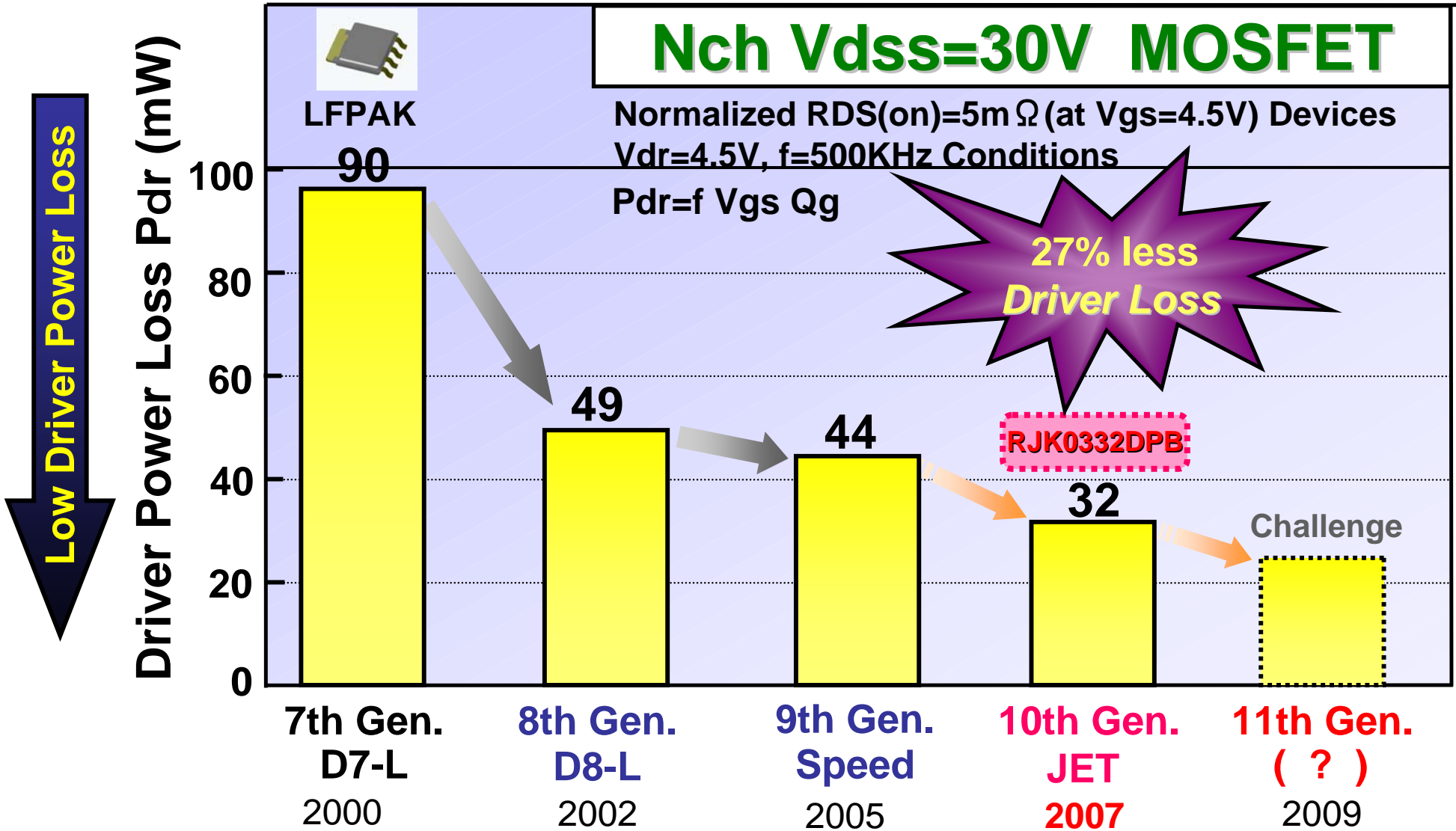
● Figure of Merit :  $FOM(R_{on} \cdot Q_g)$  at  $V_{GS}=4.5V$



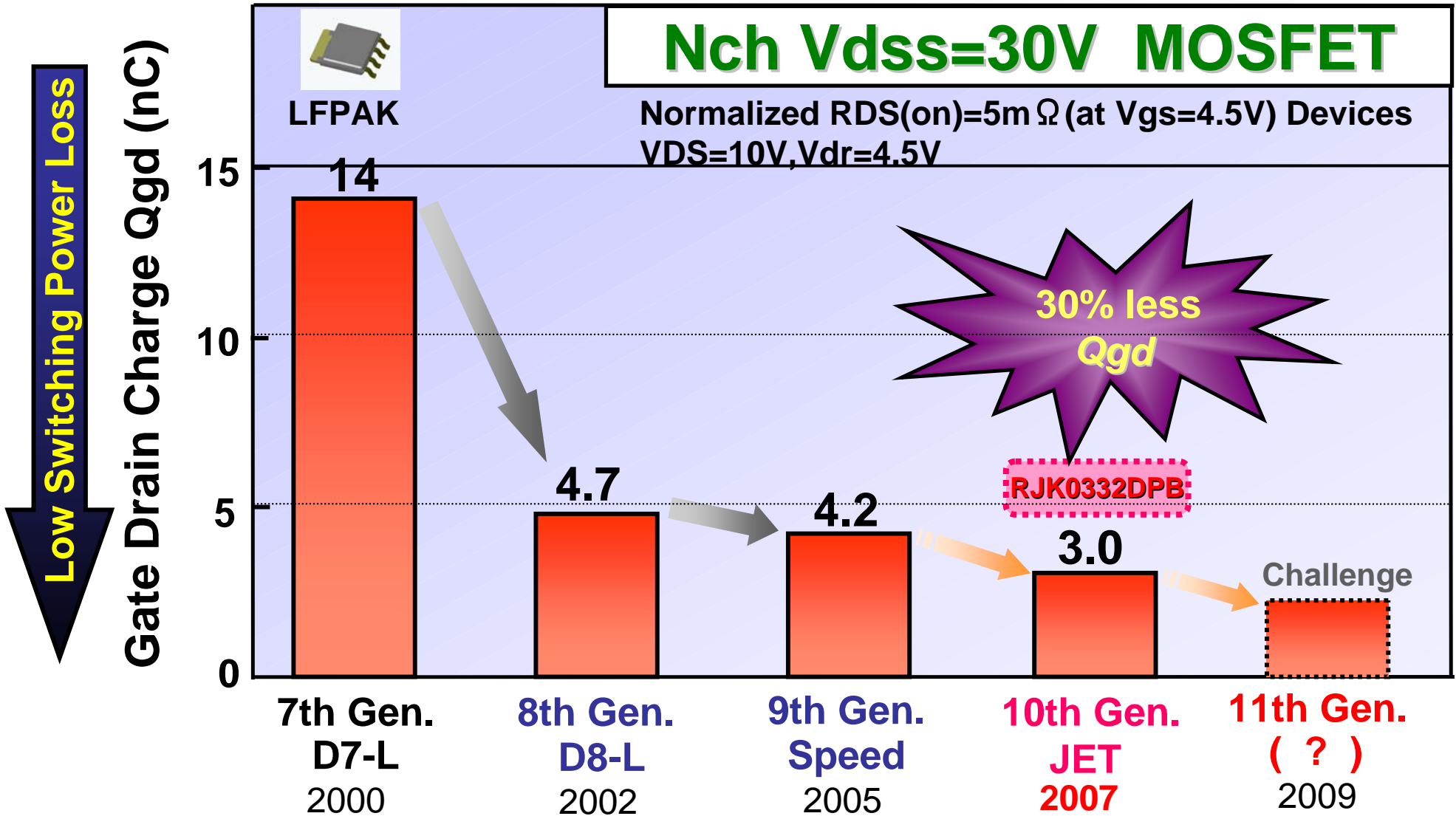
# Power MOSFET RDS(on) Trend



# Power MOSFET Qg Trend



# Power MOSFET Qgd Trend



# Feature & Merit of JET Series

(Compared with previous)

**30% Cut RDS(on)**  
**Ultra Low RDS(on)**

Reduced the Thermal  
Temperature

LFAK 1.6mΩ typ  
WPAK 1.5mΩ typ  
SOP-8 2.6mΩ typ

Capable High Current  
High Performance

High

Low On State  
Power Loss

Efficiency

Saving

Low Driver  
Power Loss

Low Switching  
Power Loss

Energy

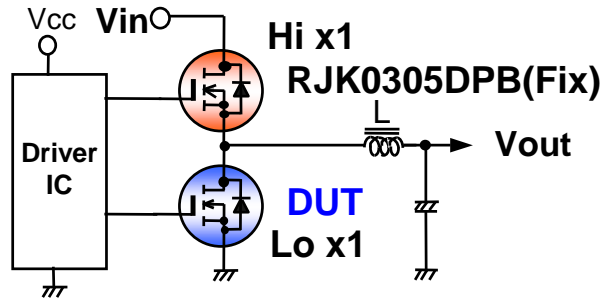
**27% Cut Qg**  
Low Qg

Achieve High Freq.  
& High Slew Rate

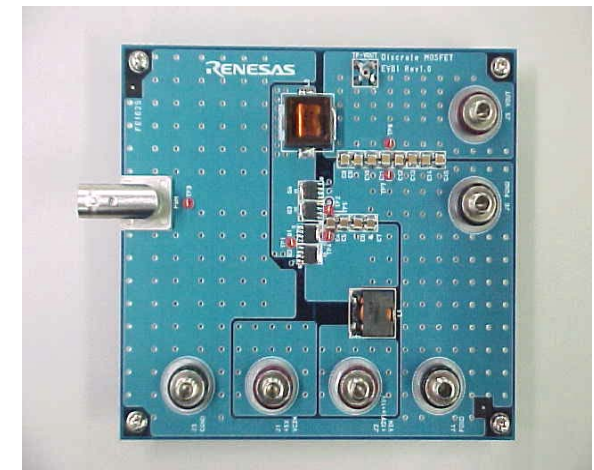
**30% Cut Qgd**  
Low Qgd

Capable Smaller & Thin Size

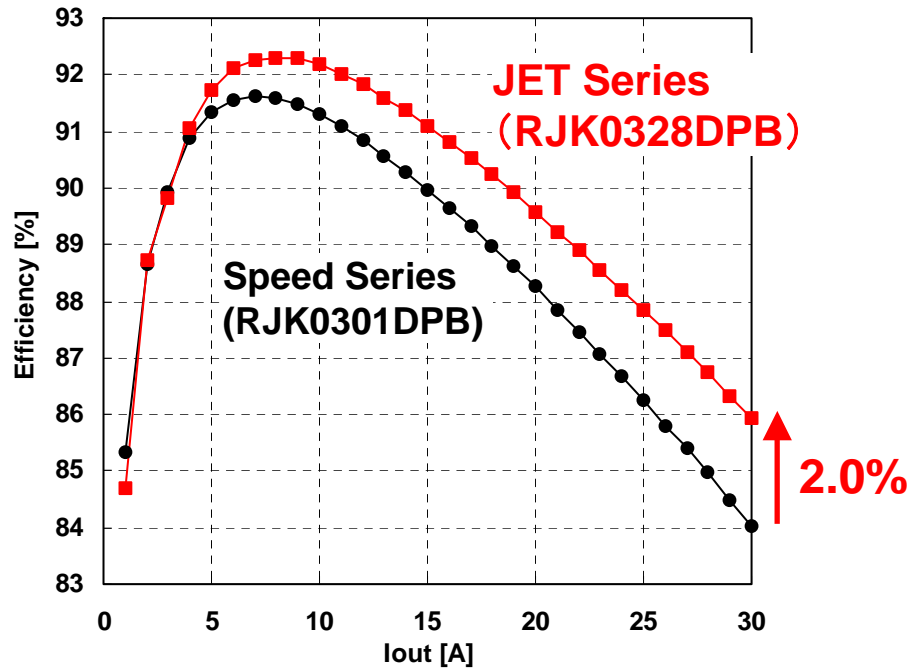
# Efficiency of JET series



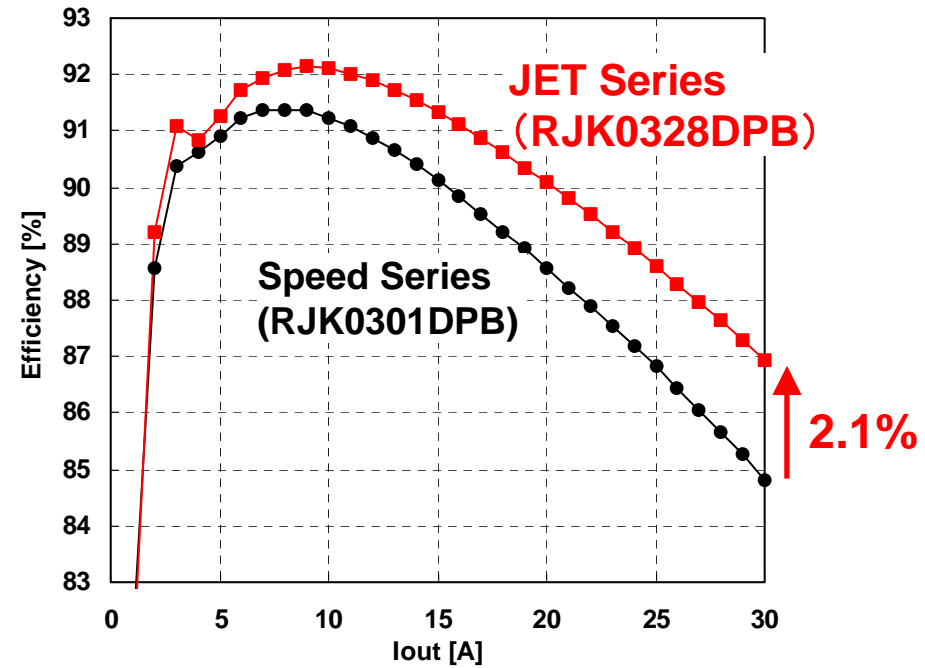
Renesas Discrete EVB  
 $T_a=25\text{deg.C}$  , No Air Flow  
 $L=0.45\mu\text{H}$



< Test Conditions >  
 $V_{IN}=12\text{V}$ ,  $V_{out}=1.2\text{V}$   
 $V_{DR}=5\text{V}$ ,  $f_{sw}=500\text{kHz}$



< Test Conditions >  
 $V_{IN}=19\text{V}$ ,  $V_{out}=1.2\text{V}$   
 $V_{DR}=5\text{V}$ ,  $f_{sw}=300\text{kHz}$



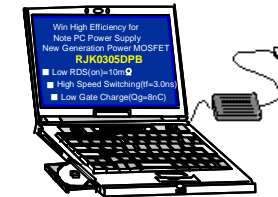
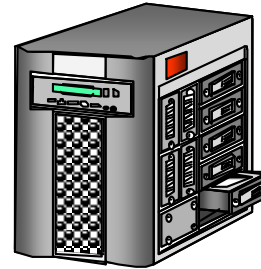
# JET Series Product Line-up



# Main Application for JET Series

## ■ VR\* for CPU Core, GPU, Chipset and Memory

Server , Network, Telecom  
Note Book PC  
VGA



## ■ Secondary Synchronous Rectification for Brick Converter and AC/DC Power Supply(Vout<5.0V)

Server , Router  
Telecom

## ■ Power Management Switch for Li+Ion Battery (N/B PC) and Oring Switch.

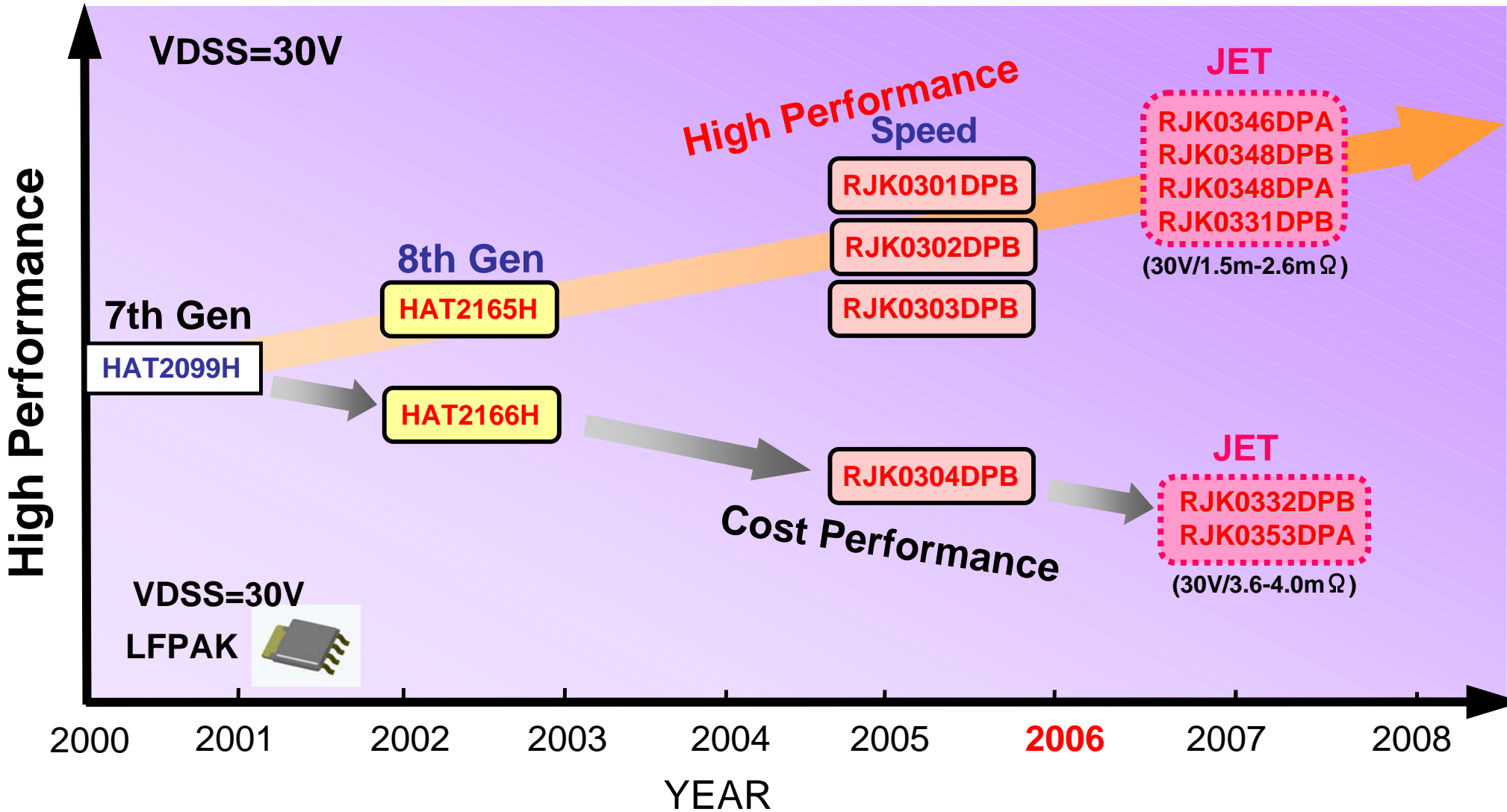
\* VR : Voltage Regulator

# JET Series Recommended List

		Hi-Side	qty/ph	Lo-Side	qty/ph	Efficiency *	Price *
<b>Server High End</b>	<b>CPU</b>	RJK0305DPB	1	RJK0332DPB	<b>2</b>	3	1
		RJK0305DPB	1	RJK0331DPB	<b>2</b>	2	2
		RJK0305DPB	1	RJK0329DPB	<b>2</b>	1	3
	<b>ChipSet</b>	RJK0305DPB	1	RJK0331DPB	1	3	1
		RJK0305DPB	1	RJK0330DPB	1	2	2
		RJK0305DPB	1	RJK0329DPB	1	1	3
	<b>Memory</b>	RJK0371DSP	1	RJK0353DSP	1	3	1
		RJK0371DSP	1	RJK0354DSP	1	2	2
		RJK0371DSP	1	RJK0355DSP	1	1	3
<b>Server Middle End</b>	<b>CPU &amp; Chipset</b>	RJK0305DPB	1	RJK0331DPB	1	3	1
		RJK0305DPB	1	RJK0330DPB	1	2	2
		RJK0305DPB	1	RJK0329DPB	1	1	3
	<b>Memory</b>	RJK0371DSP	1	RJK0353DSP	1	1	3
		RJK0371DSP	1	RJK0354DSP	1	2	2
		RJK0371DSP	1	RJK0355DSP	1	3	1

\* Rating in suggestions:  
(Best) 1 > 2 > 3

# Proposal for Synchronous Rectifier

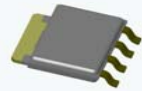


# Proposal for Isolated Brick DC/DC

Optimized Design

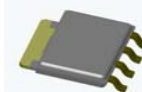
Low Ron/Qgd  
HAT2267H  
(80V/13mΩ)

LFAK  
(Wireless)



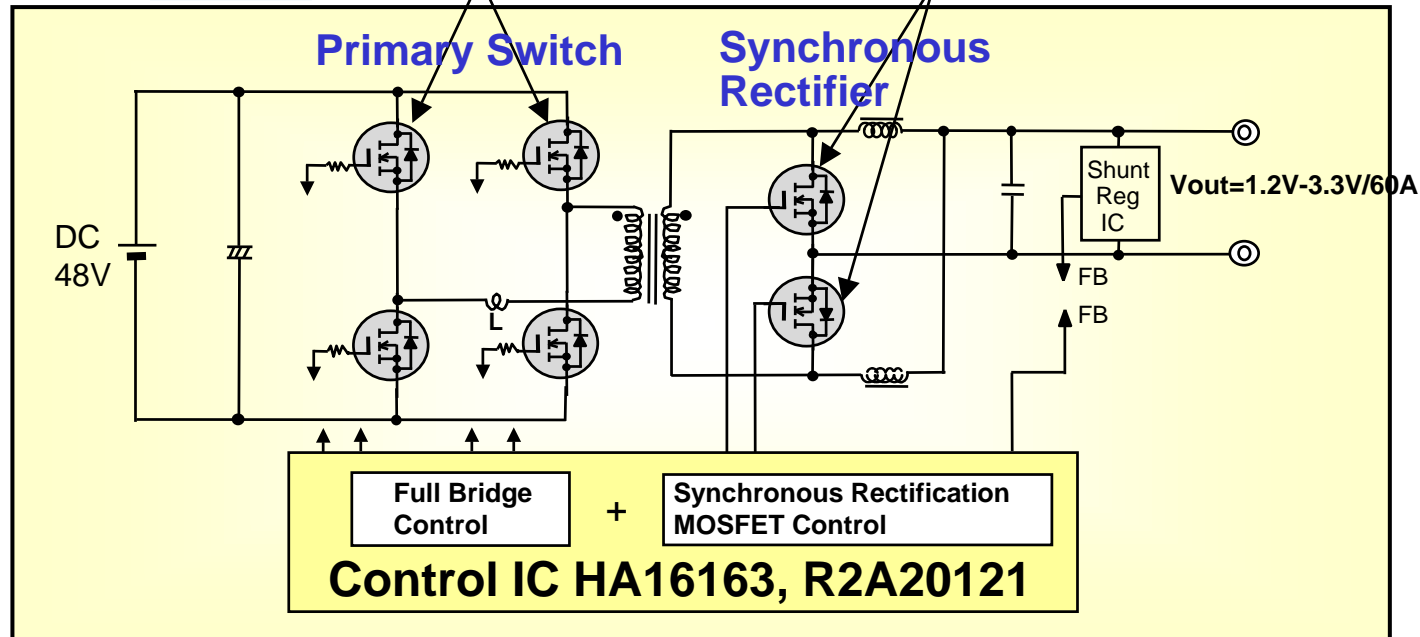
Low Ron/Qgd  
D8-L HAT2175H  
(100V/33mΩ)

Low Ron/Qg  
D8-L HAT2165H  
(30V/2.5mΩ)



Next Gen.JET  
RJK0328DPB  
(30V/1.6mΩ)

Low Loss

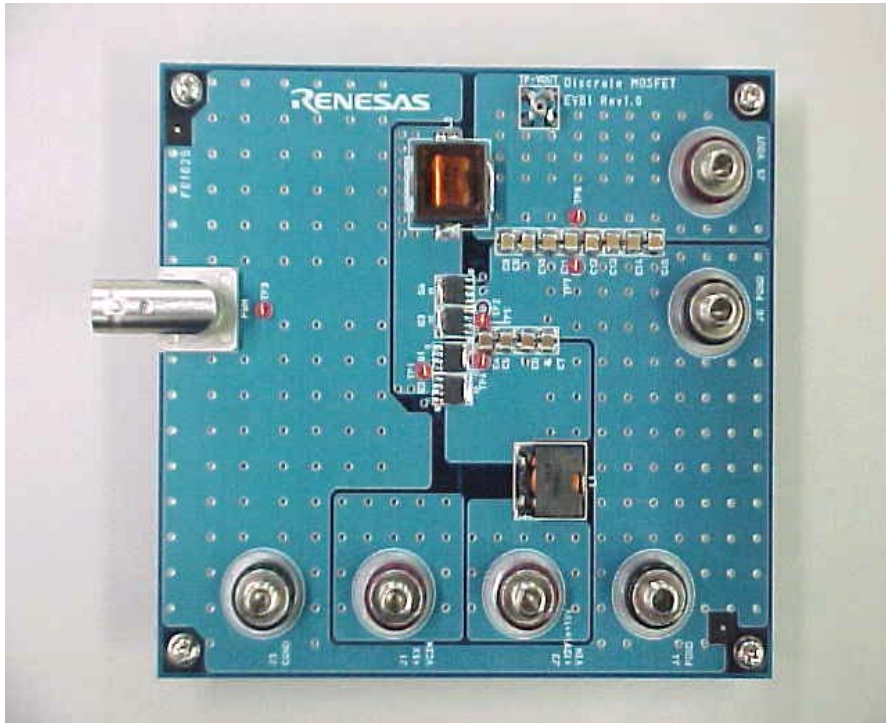


# Proposal for Brick Bus Converter

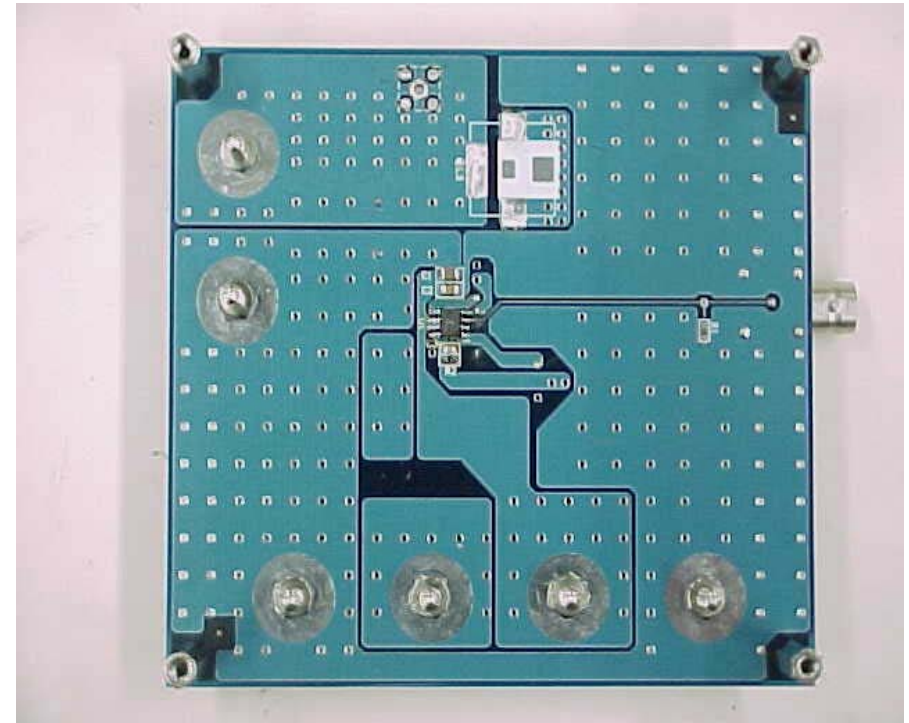
Optimized Line-up by specific application !!

Topology	Vdss	Primary SW MOSFET	Vout	SR MOSFET	
				Vdss	LFPAK/i,WPAK SOP-8
Full,Half Bridge	100V	HAT2173H HAT2175H HAT2173N	1~3.3V	30V	RJK0328DPB RJK0348DSP RJK0346DPA RJK0349DSP RJK0332DPB RJK0353DSP
	80V	HAT2267H	5.0V	40V	HAT2169H HAT2170H HAT2172H
Active Clamp	150V	HAT2183WP HAT2184WP	6~8V	60V	HAT2266H HAT2256R
	200V	HAT2187WP HAT2188WP	12V	80V	HAT2279H HAT2244WP

# Renesas Evaluation Board



< TOP VIEW >



< BOTTOM VIEW >

# **3. AC/DC Application (PFC IC, PWM Controller, DC/DC Controller)**

# RENESAS Power Supply Control IC Lineup

## PFC

### CCM

R2A20114

R2A20111

HA16174

HA16178

### CRM

R2A20112

### Interleave

R2A20113

### Single

HA16158/42

Forward, Suitable for Main

HA16141

Fly back, Suitable for AUX

## PWM (Isolation DC/DC)

R2A20121

Full Bridge,  
Suitable for large power

HA16163

HA16150

Half Bridge,  
Suitable for middle power

HA17384

Forward or Fly back,  
Suitable for small power

M51995

V-mode, Forward  
Suitable for small power

R2A20123

Quasi-Resonant mode  
Suitable for small power

## Non-Isolation DC/DC

HA16167

High efficiency  
exclude MOSFET  
Suitable for mid/Hi power

HA16114

HA16116

High input voltage(~40V)

R2A20101

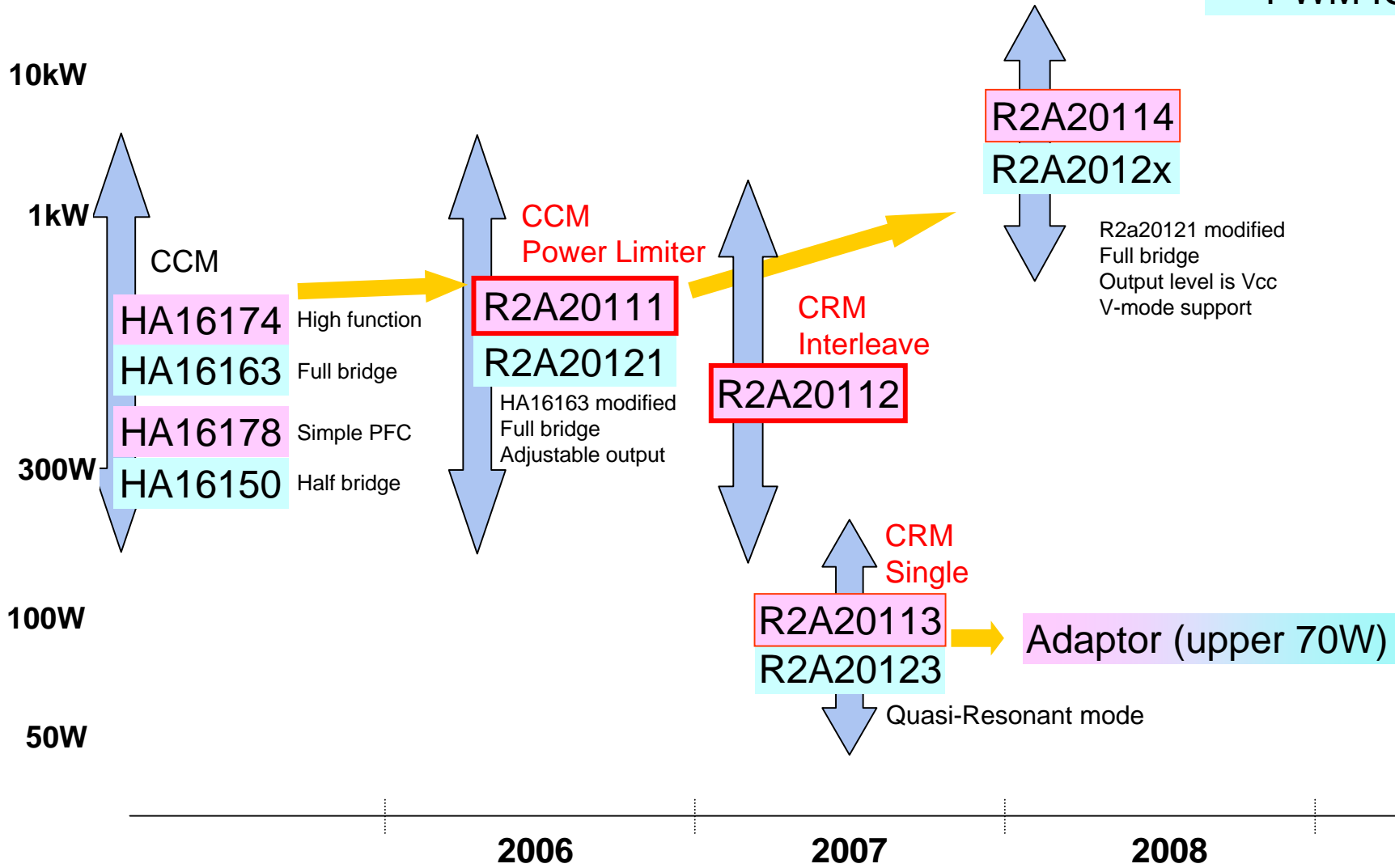
High efficiency  
include MOSFET

+



# PFC, PWM IC Development Road Map

PFC IC  
PWM IC



# PFC Control IC

# RENESAS PFC IC Lineup

	HA16178	HA16174	R2A20111	R2A20112	R2A20113
Mode	CCM	CCM	CCM	CRM	CRM
Interleave Technology				Yes	
Constant Power Limiter			Yes		
High voltage line less				Yes	Yes
gm AMP for error AMP	Yes	Yes	Yes	Yes	Yes
Feedback Loop Detector	Yes	Yes	Yes	Yes	Yes
Hold Function		Yes	Yes		
Quick Soft Start	Yes	Yes	Yes		
Power Good Function		Yes			
OVP / OCP, UVLO	Yes	Yes	Yes	Yes	Yes
Package	SOP-16 DIP-16	SOP-16 DIP-16	SOP-16 DIP-16	SOP-16 DIP-16	SOP-8 DIP-8

# CRM Interleaving PFC

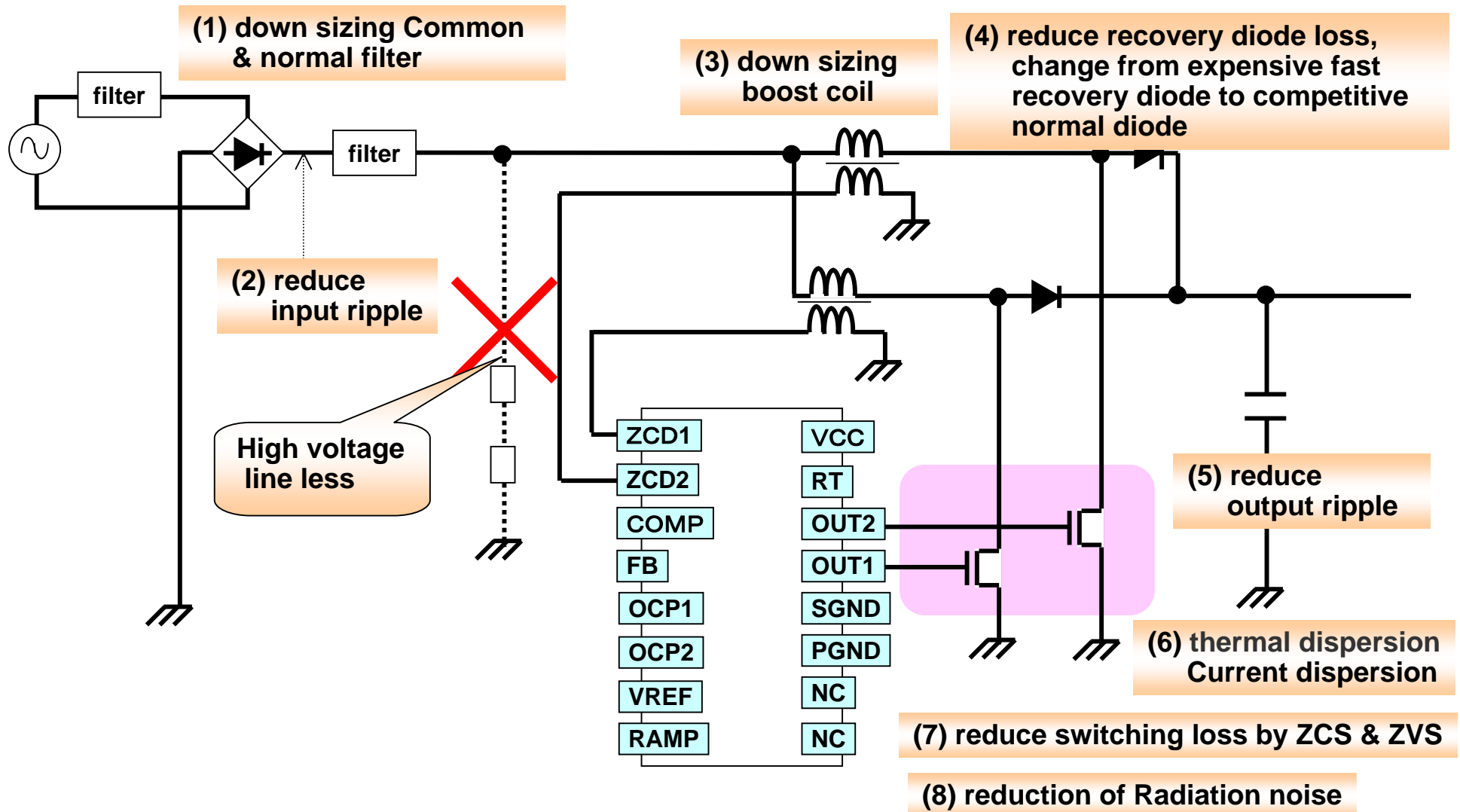
## R2A20112

Realize the advantage of both CRM and CCM

- ✓ High efficiency and Low switching noise (CRM)
- ✓ Low ripple current (Interleave)

# Advantage of CRM Interleaving PFC

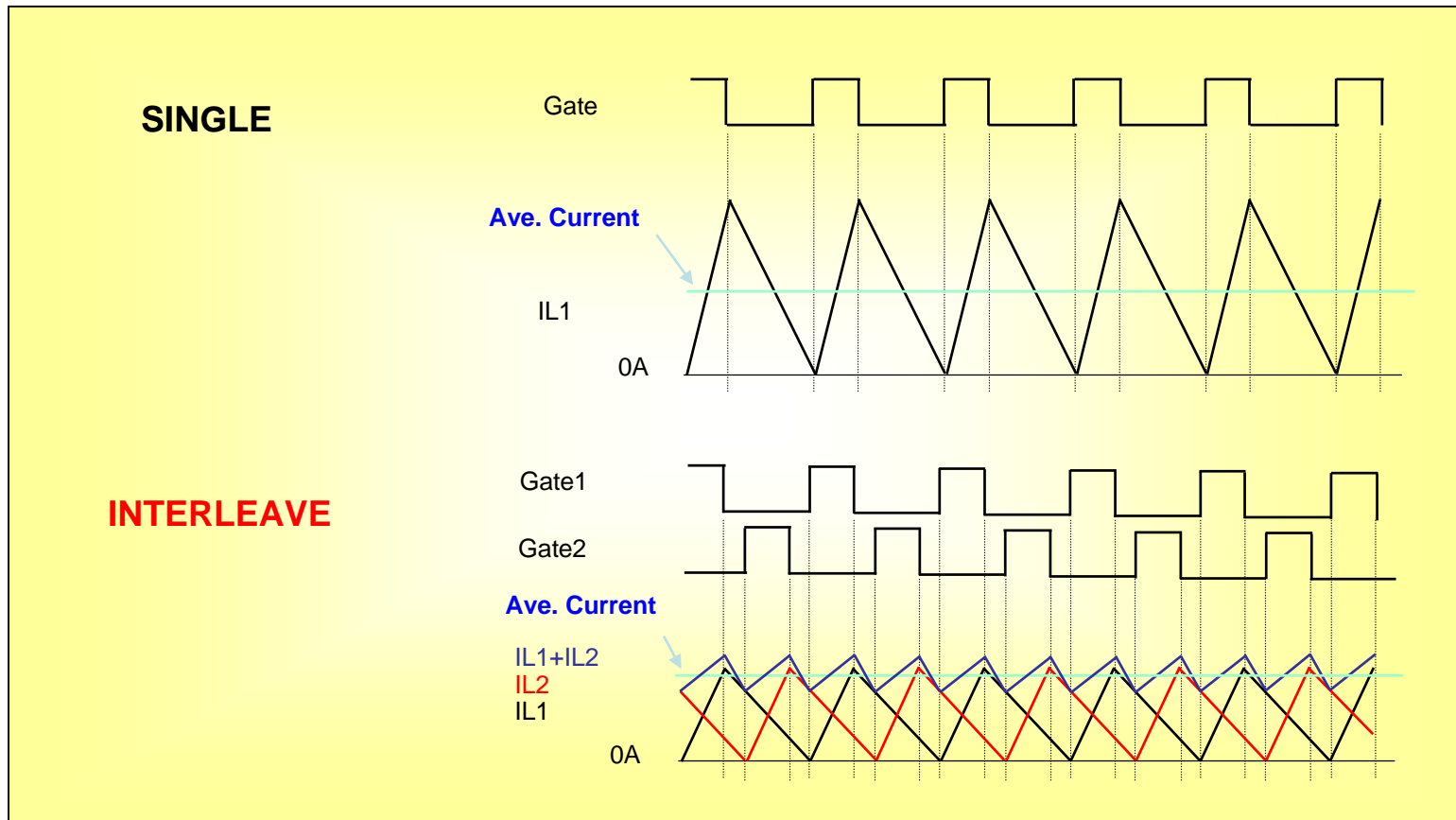
R2A20112



# Feature(1) Reduction of Line Noise & Ripple

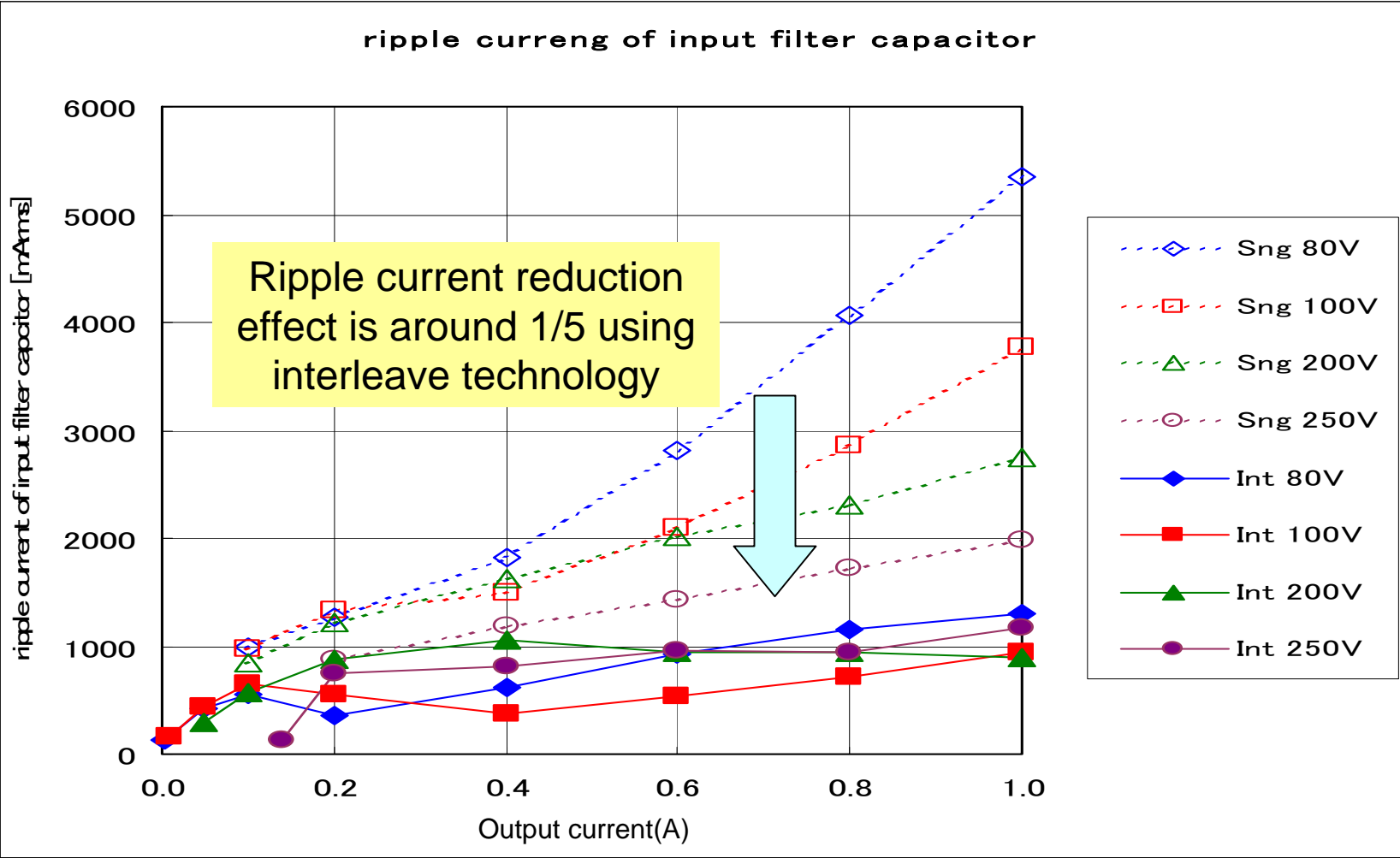
R2A20112

1. Reduce Input current ripple by interleave technology
2. Reduce switching noise of MOS FET by ZVS.
3. Reduce Diode recovery noise by ZCS.



# Feature(2) Reduction of Input Current Ripple

R2A20112

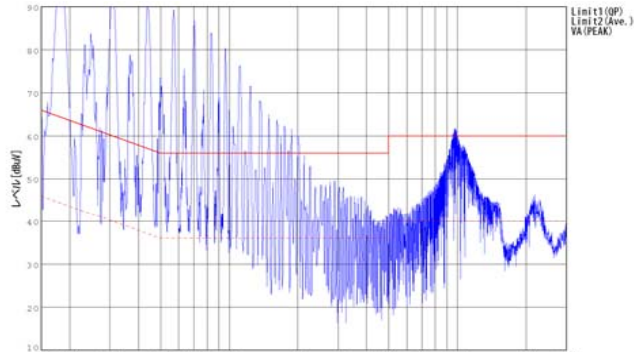


# Evaluation Result of Noise

R2A20112

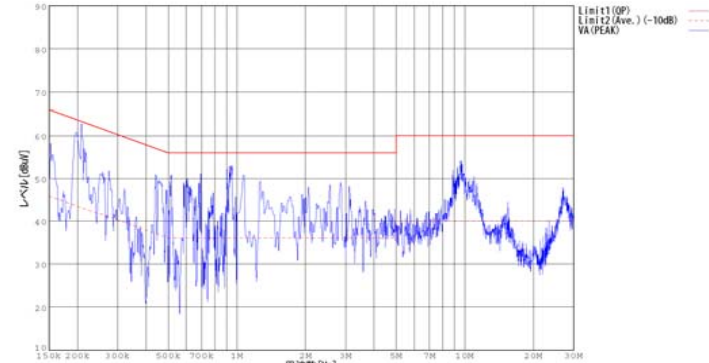
## CCM Single (R2A20111)

雑音端子電圧測定  
 機種名称 : HA16174P  
 部品番号 :  
 シリアル番号 : 01  
 測定バンド : 4バンド  
 検波モード : ヒーク  
 ラインモード : VA  
 規格1 : [VCC1] Class B(OP)  
 規格2 : [VCC1] Class B(平均値) (-10dB)  
 温度 : deq C  
 湿度 : %  
 計測器 : R3261C  
 測定日時 : 2006/10/24 20:49  
 コメント : PFC



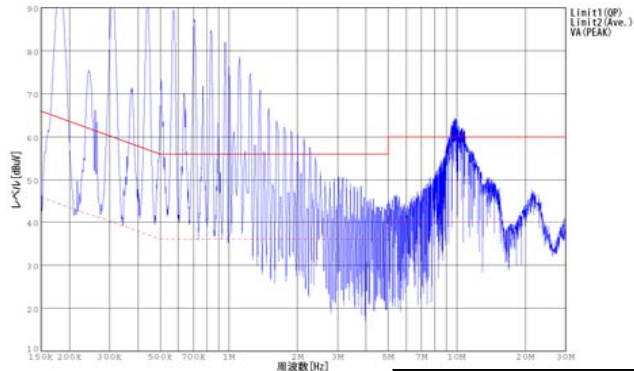
## CRM Interleave (R2A20112)

雑音端子電圧測定  
 機種名称 : R2A20112  
 部品番号 :  
 シリアル番号 : 01  
 測定バンド : 4バンド  
 検波モード : ヒーク  
 ラインモード : VA  
 規格1 : [VCC1] Class B(OP)  
 規格2 : [VCC1] Class B(平均値) (-10dB)  
 温度 : deq C  
 湿度 : %  
 計測器 : R3261C  
 測定日時 : 2006/10/24 19:45  
 コメント : PFC

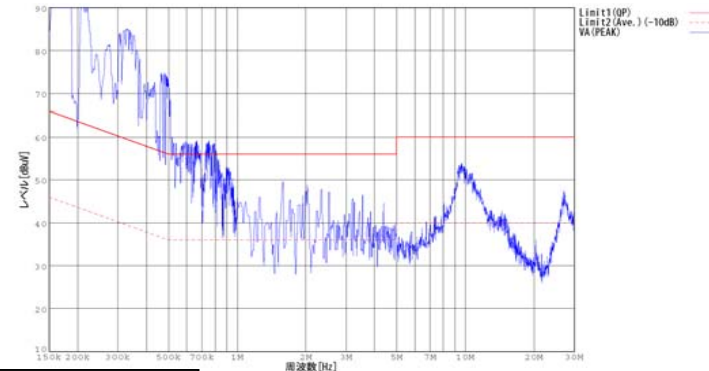


Vin=100VAC / Po=200W

雑音端子電圧測定  
 機種名称 : HA16174P  
 部品番号 :  
 シリアル番号 : 01  
 測定バンド : 4バンド  
 検波モード : ヒーク  
 ラインモード : VA  
 規格1 : [VCC1] Class B(OP)  
 規格2 : [VCC1] Class B(平均値) (-10dB)  
 温度 : deq C  
 湿度 : %  
 計測器 : R3261C  
 測定日時 : 2006/10/24 20:45  
 コメント : PFC



雑音端子電圧測定  
 機種名称 : R2A20112  
 部品番号 :  
 シリアル番号 : 01  
 測定バンド : 4バンド  
 検波モード : ヒーク  
 ラインモード : VA  
 規格1 : [VCC1] Class B(OP)  
 規格2 : [VCC1] Class B(平均値) (-10dB)  
 温度 : deq C  
 湿度 : %  
 計測器 : R3261C  
 測定日時 : 2006/10/24 19:49  
 コメント : PFC



Vin=100VAC / Po=400W

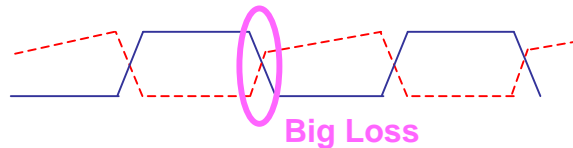


# Feature(3) Principle of Power Loss Reduction

R2A20112

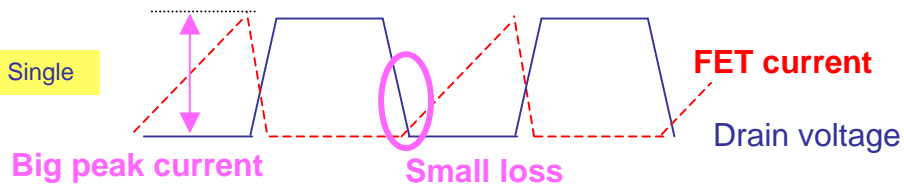
## Concept of power loss each mode

Single CCM



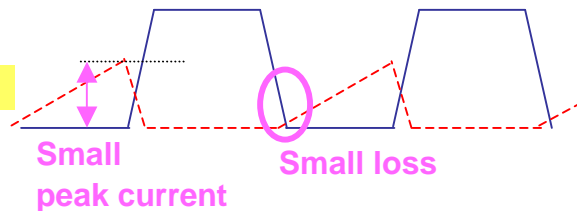
In CCM case, a peak current is small, but switching loss is big at Ton.

CRM Single



In CRM case, switching loss is small, but peak current is so big.

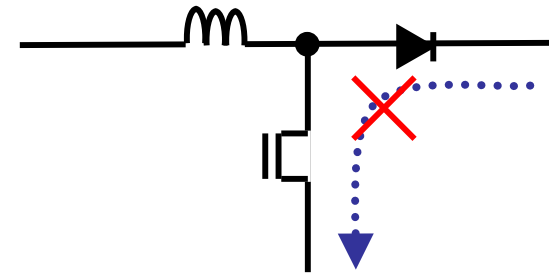
CRM inter leave



To sift CRM interleave, it is possible to keep small loss at Ton, and keep small peak current.

## Recovery Loss of Boost diode by ZCS

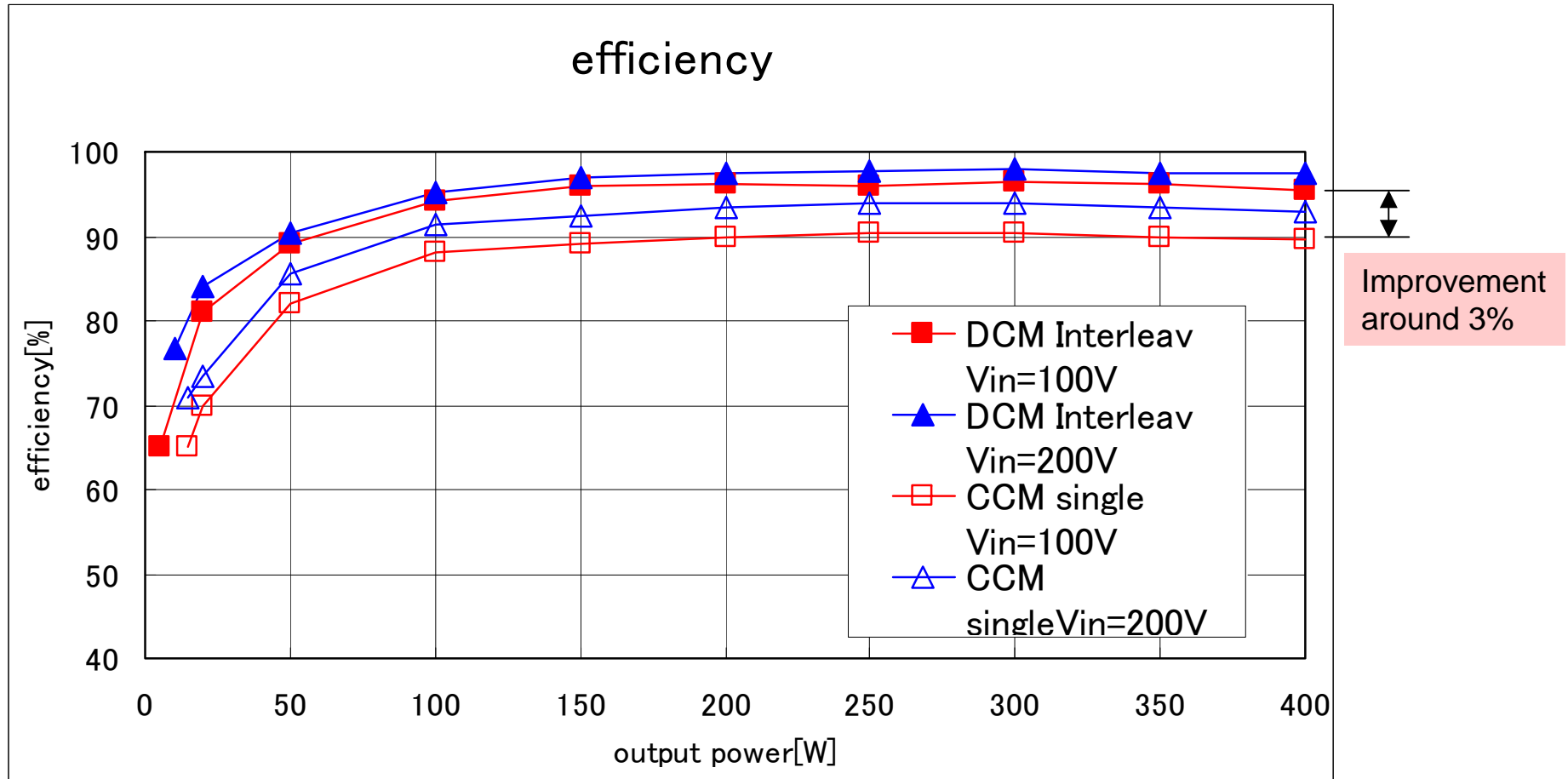
Basically no recovery diode loss by sensing Zero current



# Feature(3) Evaluation Data

R2A20112

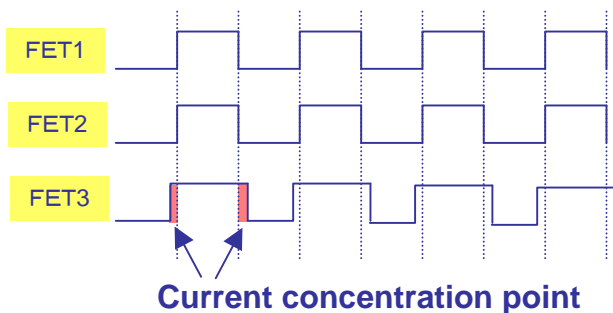
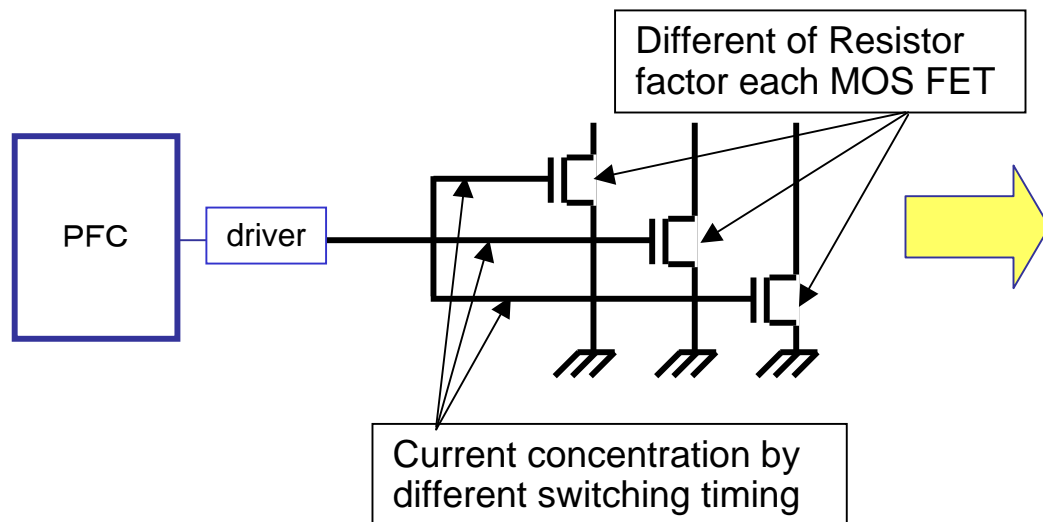
## Improvement of efficiency by using CRM Interleave



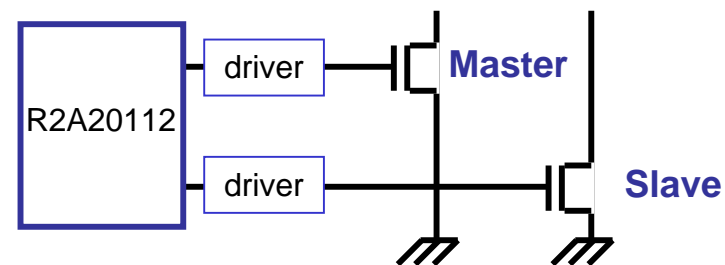
# Feature(4) Improvement of Thermal Balance

R2A20112

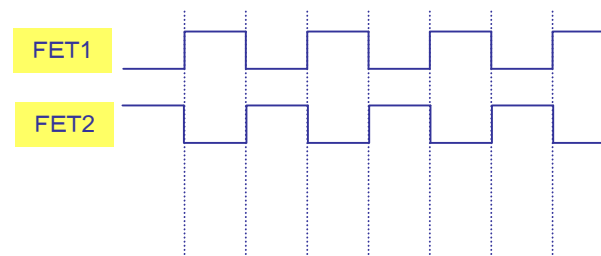
## Parallel switching by Single Mode



## Independent control by Interleave



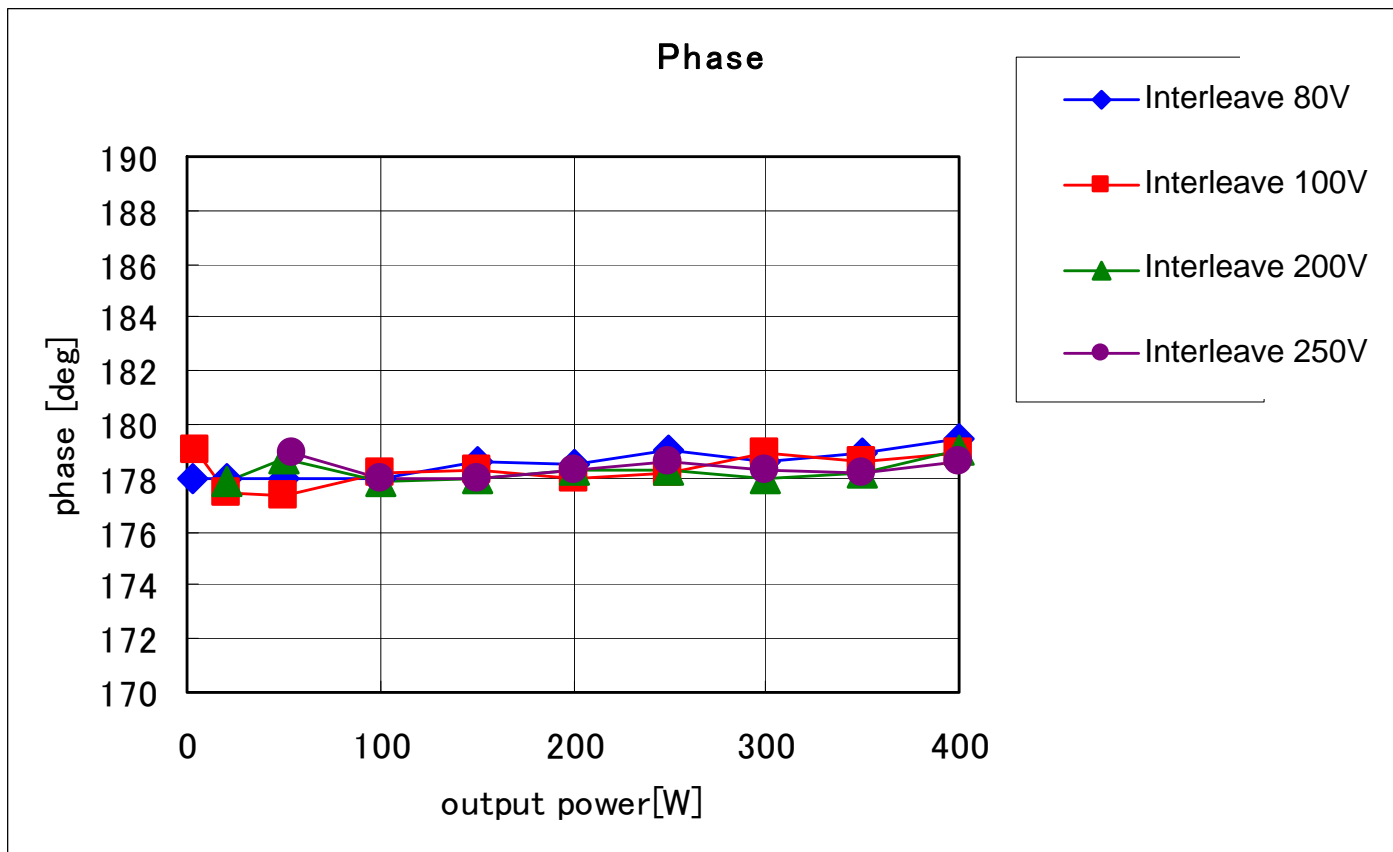
Reduce unbalance by independence control



# Evaluation Result of Phase Shift

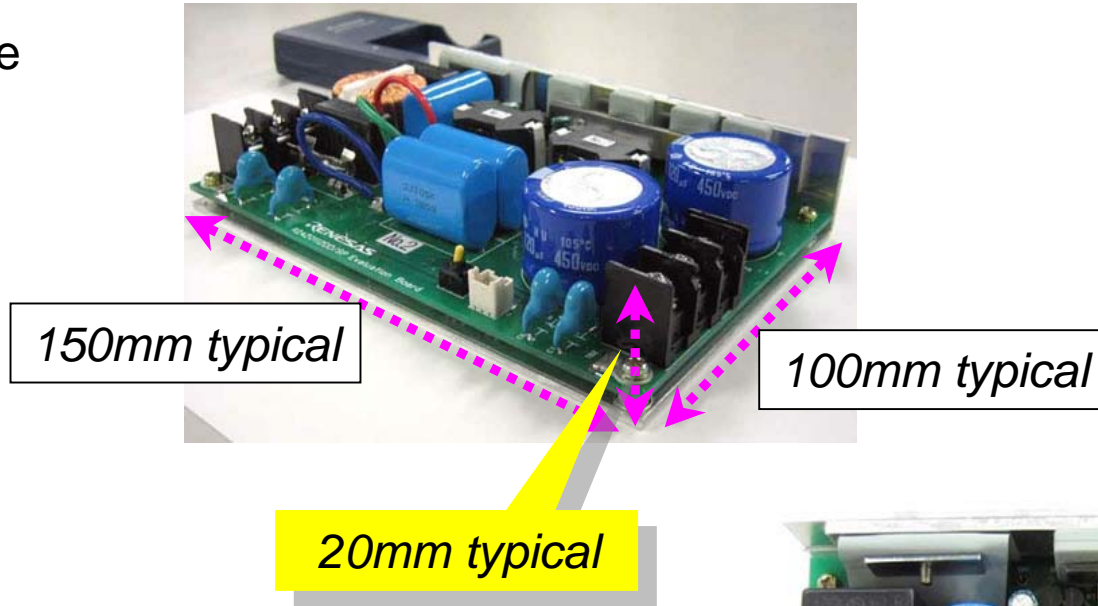
R2A20112

Phase control system realizes suitable timing between Master and Slave.



# Small size Demo Board of R2A20112

(1) size

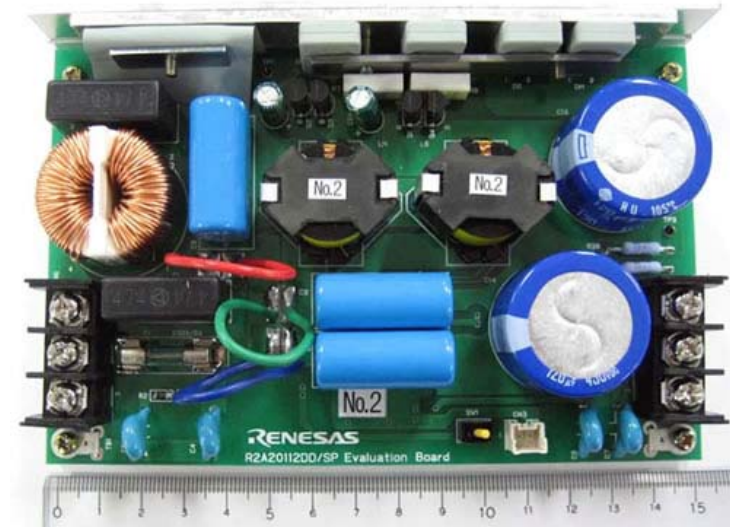


(2) Electrical characteristic

$V_{in}=85V$  to  $265V$

$V_{out}=385V$

**$P_o=0$  to  $400W$**



# PWM Controller IC

## Bridge structure (Half Bridge, Full Bridge)

- ✓ Trance down sizing
- ✓ Available to use 500V MOS FET (In Forward case, it needs 800V type MOS FET)
- ✓ Available to use Low resistor factor type MOS FET (same reason)

## Full Bridge structure

- ✓ High efficiency by ZVS(zero voltage switching) technology.

# R2A20121 Feature [ Full Bridge Control IC ]

R2A20121

Phase shift control by Delay adjustment

Reduced switching loss  
by ZVS operation  High efficiency

Secondary side Delay adjustment

Reduced Body-diode  
conduction loss  High efficiency

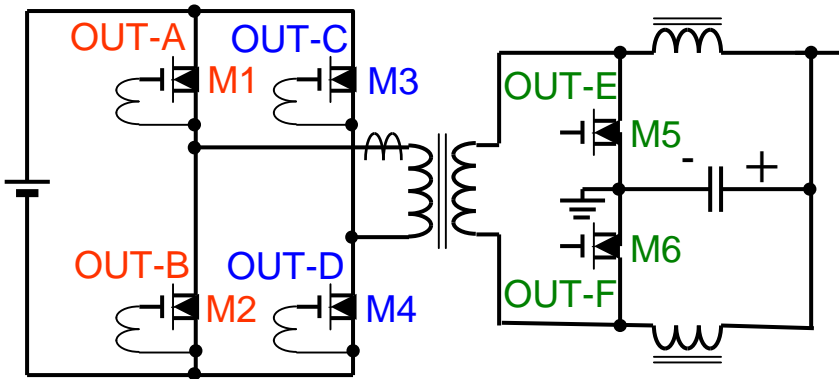
High frequency switching

2MHz max. OSC. frequency  Down sizing transe  
& capacitor



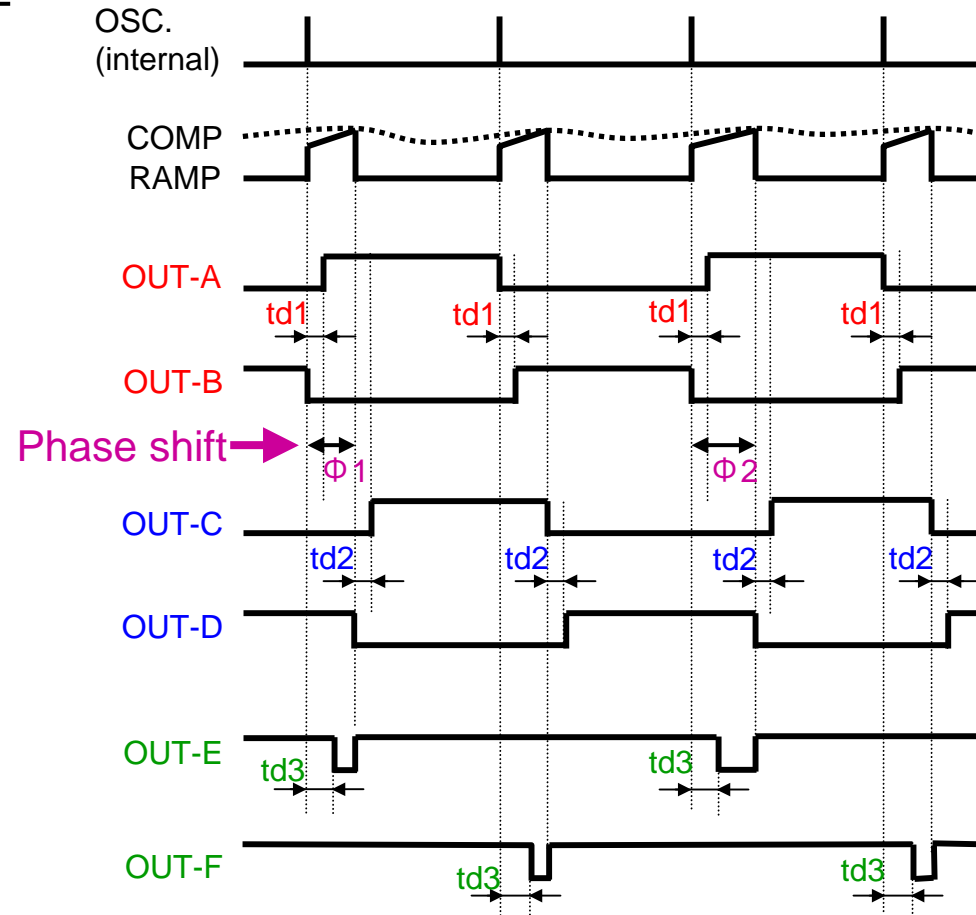
# Phase Shift Control by Delay Adjust

R2A20121



## Delay Adjust

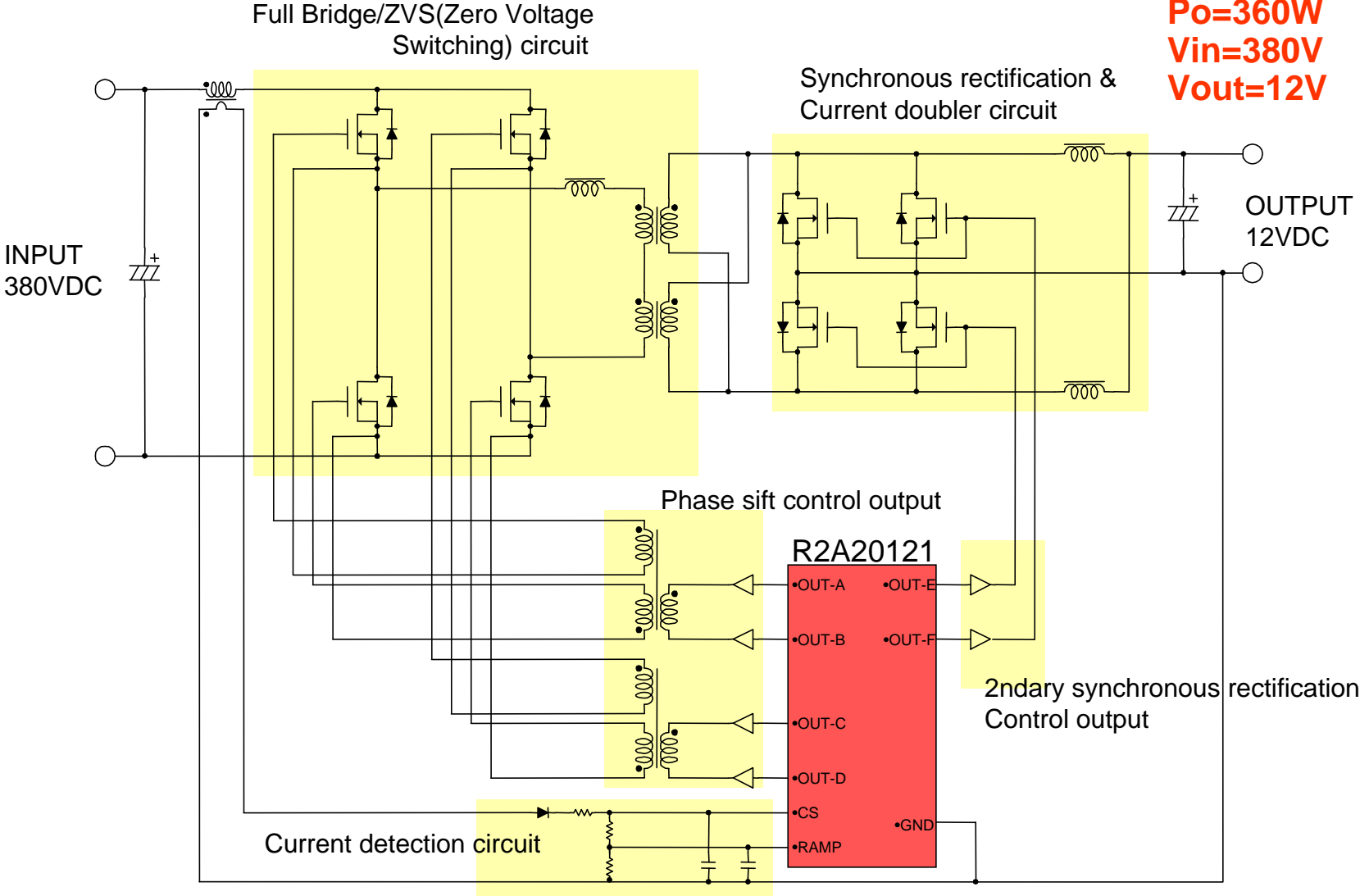
- ✓ Primary side for ZVS
  - td1 : For M1 & M2
  - td2 : For M3 & M4
- ✓ Secondary side to minimize Body-diode conduction loss
  - td3 : For M5 & M6



# Evaluation Board Circuit

R2A20121

Efficiency: 92.7%  
 Po=360W  
 Vin=380V  
 Vout=12V



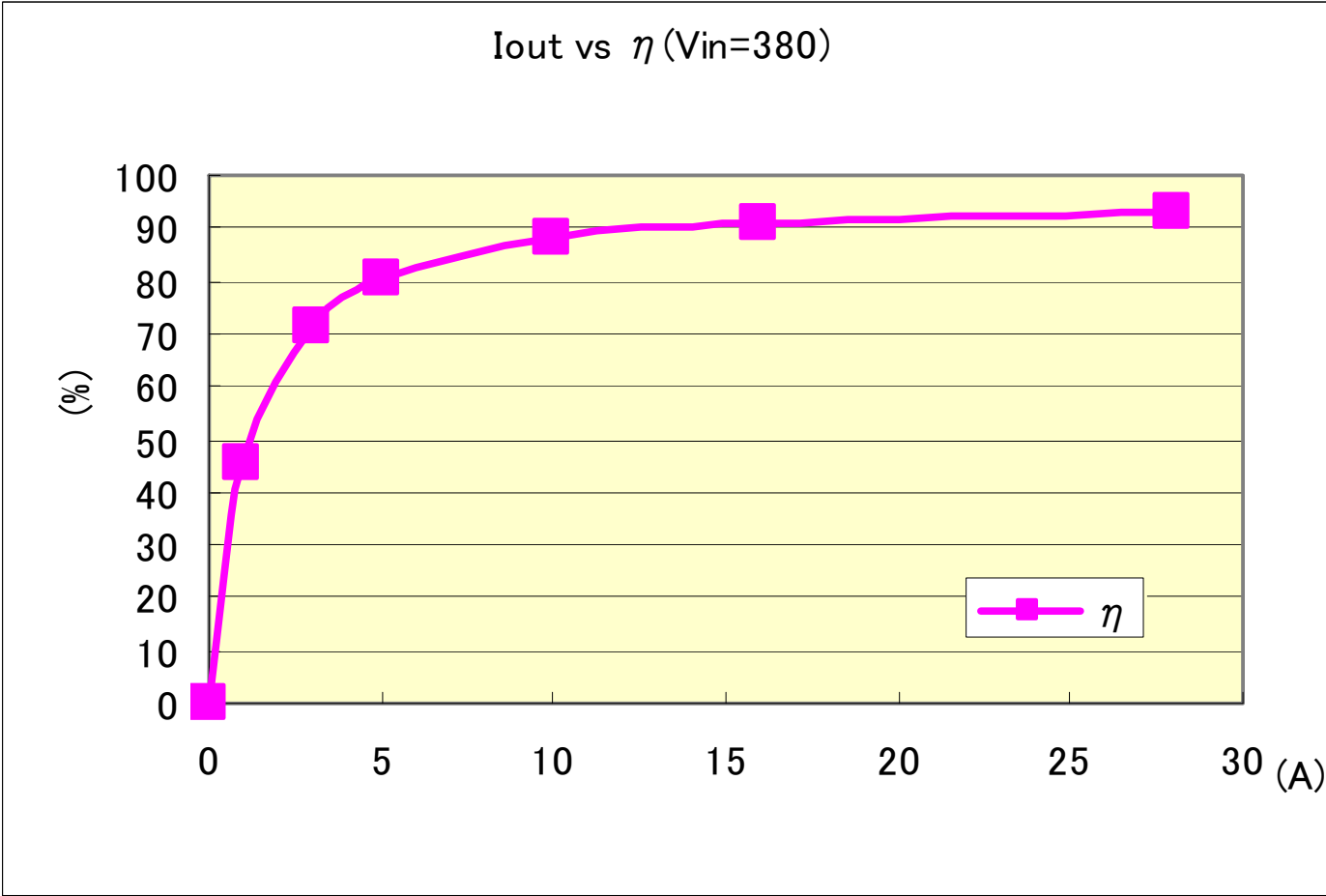
# Evaluation Board

R2A20121



12.5cm/400W

# Efficiency on Evaluation Board



# DC/DC Controller IC

# DC-DC converter Lineup (1)

## Standard DC-DC

	Conversion type	Operating Voltage	Operating Current (typ.)	Output Type	Output Voltage	Output current (max.)	SW Freq.	Max. ON Duty	Other Function	Package		
										DIP	SOP	SSOP
M5291	Step-up Step-down Inverting	2.5 to 40V	1.4mA	Open Collector	Adjustable	200mA	100Hz to 100kHz	85.7%	Peak current limitation	P (8)	FP (8)	-
M62212		2.5 to 18V	1.3mA			150mA	to 300kHz	0 to 100% (Adjustable with DTC terminal)	ON/OFF control SCP, DTC Soft start	P (8)	FP (8)	GP (8)
M62211	Step-up Step-down Inverting BL control	2.5 to 35V		Totem-pole	to 500kHz				90%	2 input priority control ON/OFF control SCP, DTC Soft start External Sync. Input	P (14)	FP (10)
M62215		8.6 to 25V	9.5mA			2 input priority control ON/OFF control SCP, DTC Soft start External Sync. Input Pulse by pulse CLM	-	FP (10)		-		
M62216	Step-up Step-down	0.9 to 15V	850uA	Open collector	Adjustable	100mA	155kHz	87%	ON/OFF control	-	FP (8)	GP (8)
HA16114	Step-down Inverting	3.9 to 40V	8.5mA	Totem-pole		to 600kHz	+/-1A	0 to 100% (Adjustable with DB terminal)	ON/OFF control Pulse by pulse CLM Intermittent operation by timer External Sync. Input(HA16114/120) Soft start Quick shut High accuracy reference voltage Vref OVP	P (16)	FP (16)	-
HA16120	Step-up				-					FP (16)	-	
HA16116	CH1:Step-down :Inverting CH2:Step-down				-					FP (20)	-	
HA16121	CH1:Step-down :Inverting CH2:Step-up				-					FP (20)	-	

# DC-DC converter Lineup (2)

## Fixed output voltage type DC-DC

	Conversion type	Operating Voltage	Operating Current (typ.)	Output Type	Output Voltage	Output current (max.)	SW Freq.	Max. ON Duty	Other Function	Package			
										SIP	SOP	SOT	
M62220 M62221 M62222	Step-down	4 to 15V	660uA	Open collector	220:3.3V 221:3.0V 222:2.7V	100mA	110kHz	90%	OCP	L (5)	FP (8)	-	
M62270 M62271 M62272 M62273 M62274 M62275 M62276			500uA		270:3.3V 271:3.0V 272:2.7V 273:2.4V 274:2.1V 275:1.8V 276:1.5V					-	-	GP (5)	
M62290			780uA		5.0V					L (5)	FP (8)	-	
M62291		570uA	-			-	GP (5)						
M62292 M62293 M62294 M62203		4 to 15V	1.0mA		292:3.3/1.8V 293:3.3/2.5V 294:3.3/2.0V 203:3.3/2.7V	30mA	110kHz			-	FP (8)	-	Reset circuit for power supply(5V) and regulator output(3.3V)

## POL converter

	Conversion type	Operating Voltage	Operating Current (typ.)	Output Type	Output Voltage	Output current (max.)	SW Freq.	Output MOSFET	Other Function	Package		
										TSSOP	QFN	CSP
HA16167	Step-down	4.5 to 14.5V	3.6mA	Sync. Rectifying	Adjustable	200mA	to 1MHz	-	ON/OFF control	A (20)	-	-
R2A20101		2.5 to 5.5V	45uA (Quiescent)			650mA	to 2MHz	Built-in	ON/OFF control Power Good	-	NP (24)	BM (15)

# DC-DC converter Lineup (3)

## Multi channel DC-DC

	Ch. No.	Conversion type	Operating Voltage	Operating Current (typ.)	Output Voltage	Output current (max.)	Rect. Type	Built-in components			SW Freq.	Max. ON Duty	Application	Other Function	Package	
								MOS FET	Load SW	Phase Comp.					QFN	LGA
M62298	CH1	Step-up	2.5 to 6.0V	5.0mA	5.8V	50/-100mA *2	Diode	-	-	-	500kHz	85%	Motor	ON/OFF ctrl Soft start OVP,OCP,SCP	FP (52)	-
	CH2	Step-down			3.35V	800mA	Diode	Built-in	-	-			SOC I/O,MCU			
	CH3	Step-down			1.85V	500mA	Sync.	Built-in	-	-			SOC core			
	CH4	Step-down			3.45V	300mA	Diode	Built-in	-	-			CCD AFE			
	CH5	Step-up			12V/-6.5V *1	200mA	Diode	Built-in	-	-			CCD(+),(-)			
	CH6	Step-up			12V	200mA	Diode	Built-in	-	-			LCD			
	CH7	Step-up			CC:20mA	200mA	Diode	Built-in	-	-			LCD BL			
M62299	CH1	Step-up	1.2 to 6.0V	5.0mA	5.0V	50/-100mA *2	Diode	-	-	-	500kHz	95%	Motor	ON/OFF ctrl Soft start OVP,OCP,SCP	FP (48)	WG (49)
	CH2	Step-down			3.35V	800mA	Diode	Built-in	-	-			SOC I/O,MCU			
	CH3	Step-down			1.2V	500mA	Sync.	Built-in	-	-			SOC core			
	CH4	Step-down			3.45V	300mA	Diode	Built-in	-	-			CCD AFE			
	CH5	Step-up			12V	200mA	Diode	Built-in	-	-			CCD(+)			
	CH6	Inverting			-6.5V	10/-20mA *2	Diode	-	-	-			CCD(-)			
	CH7	Step-up			CC:20mA	200mA	Diode	Built-in	-	-			LCD BL			
R2A20010	CH1	Step-up	1.2 to 6.0V	4.0mA	5.0V	600mA	Sync.	Built-in	Built-in	Built-in	1MHz	95%	Motor	ON/OFF ctrl Soft start Current mode Bootstrap Dimmer ctrl OVP,OCP,SCP	NP (48)	LG (49)
	CH2	Step-down			3.3V	400mA	Sync.	Built-in	-	Built-in			SOC I/O,MCU			
	CH3	Step-down			3.3V	400mA	Sync.	Built-in	-	Built-in			CCD AFE			
	CH4	Step-down			1.8V/2.5V	300mA	Sync.	Built-in	-	Built-in			Memory			
	CH5	Step-down			1.2V	500mA	Sync.	Built-in	-	Built-in	SOC core					
	CH6	Step-up			15V	50mA	Diode	-	-	Built-in	CCD(+)					
	CH7	Inverting			-7.5V	100mA	Diode	-	-	Built-in	CCD(-)					
	CH8	Step-up			CC:20mA	50mA	Diode	-	Built-in	Built-in	LCD BL					

\*1) Need the transformer externally.

\*2) Output sink/source current for external MOSFET



